

CY8C41xx

Features

- 32-bit MCU subsystem
 - 48 MHz Arm® Cortex®-M0+ CPU with single-cycle multiply
 - Up to 64 KB of flash with read accelerator
 - Up to 8 KB of SRAM
- Programmable analog
 - Two opamps with reconfigurable high-drive external and high-bandwidth internal drive and Comparator modes and ADC input buffering capability. Opamps can operate in deep sleep low-power mode
 - 12-bit 1-MspS SAR ADC with differential and single-ended modes, and channel sequencer with signal averaging
 - Single-slope 10-bit ADC function provided by a capacitance sensing block
 - Two current DACs (IDACs) for general-purpose or capacitive sensing applications on any pin
 - Two low-power comparators that operate in Deep Sleep low-power mode
- Programmable digital
 - Programmable logic blocks allowing boolean operations to be performed on port inputs and outputs
- Low-power 1.71-V to 5.5-V operation
 - Deep Sleep mode with operational analog and 2.5- μ A digital system current
- Capacitive sensing
 - Capacitive sigma-delta provides best-in-class signal-to-noise ratio (SNR) (>5:1) and water tolerance
 - Infineon-supplied software component makes capacitive sensing design easy
 - Automatic hardware tuning (SmartSense)
- LCD drive capability
 - LCD segment drive capability on GPIOs
- Serial communication
 - Three independent run-time reconfigurable serial communication blocks (SCBs) with reconfigurable I²C, SPI, or UART functionality
- Timing and pulse-width modulation
 - Five 16-bit Timer/Counter/Pulse-width Modulator (TCPWM) blocks
 - Center-aligned, edge, and pseudo-random modes
 - Comparator-based triggering of kill signals for motor drive and other high-reliability digital logic applications
 - Quadrature decoder
- Up to 36 programmable GPIO pins
 - 48LD TQFP, 44LD TQFP, 40L QFN, 32-lead QFN, and 35-ball WLCSP packages
 - Any GPIO pin can be CAPSENSE™, analog, or digital
 - Drive modes, strengths, and slew rates are programmable
- Clock sources
 - 32 kHz watch crystal oscillator (WCO)
 - $\pm 2\%$ internal main oscillator (IMO)
 - 32 kHz internal low-power oscillator (ILO)
- ModusToolbox™ software
 - Comprehensive collection of multi-platform tools and software libraries
 - Includes board support packages (BSPs), peripheral driver library (PDL), and middleware such as CAPSENSE™

Description

- PSoC™ Creator design environment
 - Integrated development environment (IDE) provides schematic design entry and build, with analog and digital automatic routing
 - Application programming interface (API) components for all fixed-function and programmable peripherals
- Industry-standard tool compatibility
 - After schematic entry, development can be done with Arm®-based industry-standard development tools

Description

PSoC™ 4 is a scalable and reconfigurable platform architecture for a family of programmable embedded system controllers with an Arm® Cortex®-M0+ CPU. It combines programmable and reconfigurable analog and digital blocks with flexible automatic routing. The PSoC™ 4100S product family is a member of the PSoC™ 4 platform architecture. It is a combination of a microcontroller with standard communication and timing peripherals, a capacitive touch-sensing system (CAPSENSE™) with best-in-class performance, programmable general-purpose continuous-time and switched-capacitor analog blocks, and programmable connectivity. PSoC™ 4100S products are upward compatible with members of the PSoC™ 4 platform for new applications and design needs.

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1 Development ecosystem

1.1 PSoC™ 4 MCU resources

Infineon provides a wealth of data at www.infineon.com to help you select the right PSoC™ device and quickly and effectively integrate it into your design. The following is an abbreviated, hyperlinked list of resources for PSoC™ 4 MCU:

- **Overview:** [PSoC™ Portfolio](#)
- **Product selectors:** [PSoC™ 4 MCU](#)
- **Application notes** cover a broad range of topics, from basic to advanced level, and include the following:
 - [AN79953](#): Getting Started With PSoC™ 4 MCU. This application note has a convenient flow chart to help decide which IDE to use: [ModusToolbox™ software](#) or [PSoC™ Creator](#)
 - [AN88619](#): PSoC™ 4 hardware design considerations
 - [AN73854](#): PSoC™ Creator - Introduction to bootloaders
 - [AN89610](#): PSoC™ Arm® Cortex® code optimization
 - [AN86233](#): PSoC™ 4 MCU low-power modes and power reduction techniques
 - [AN57821](#): Mixed signal circuit board layout considerations
 - [AN85951](#): PSoC™ 4 and PSoC™ 6 CAPSENSE™ design guide
- **Code examples** demonstrate product features and usage, and are also available on [Infineon GitHub](#) repositories.
- **Reference manuals** provide detailed descriptions of PSoC™ 4 MCU architecture and registers.
- **PSoC™ 4 MCU programming specification** provides the information necessary to program PSoC™ 4 MCU non-volatile memory.
- **Development tools**
 - ModusToolbox™ software enables cross platform code development with a robust suite of tools and software libraries.
 - PSoC™ Creator is a free Windows-based IDE. It enables concurrent hardware and firmware design of PSoC™ 3, PSoC™ 4, PSoC™ 5LP, and PSoC™ 6 MCU based systems. Applications are created using schematic capture and over 150 pre-verified, production-ready peripheral components.
 - [CY8CKIT-041-41XX](#) PSoC™ 4100S CAPSENSE™ Pioneer Kit, is an easy-to-use and inexpensive development platform. This kit includes connectors for Arduino™ compatible shields.
 - [MiniProg4](#) and [MiniProg3](#) all-in-one development programmers and debuggers.
- **PSoC™ 4 MCU CAD libraries** provide footprint and schematic support for common tools. [IBIS models](#) are also available.
- **Training Videos** are available on a wide range of topics including the [PSoC™ 4 MCUs](#).
- **Infineon developer community** enables connection with fellow PSoC™ developers around the world, 24 hours a day, 7 days a week, and hosts a dedicated [PSoC™ 4 MCU community](#).

1.2 ModusToolbox™ software

ModusToolbox™ software is Infineon' comprehensive collection of multi-platform tools and software libraries that enable an immersive development experience for creating converged MCU and wireless systems. It is:

- Comprehensive - it has the resources you need
- Flexible - you can use the resources in your own workflow
- Atomic - you can get just the resources you want

Infineon provides a large collection of code [repositories on GitHub](#), including:

- Board support packages (BSPs) aligned with Infineon kits

1 Development ecosystem

- Low-level resources, including a peripheral driver library (PDL)
- Middleware enabling industry-leading features such as CAPSENSE™
- An extensive set of thoroughly tested [code example applications](#)

ModusToolbox™ software is IDE-neutral and easily adaptable to your workflow and preferred development environment. It includes a project creator, peripheral and library configurators, a library manager, as well as the optional Eclipse IDE for ModusToolbox™, as [Figure 1](#) shows. For information on using Infineon tools, refer to the documentation delivered with ModusToolbox™ software, and [AN79953: Getting Started with PSoC™ 4 MCU](#).

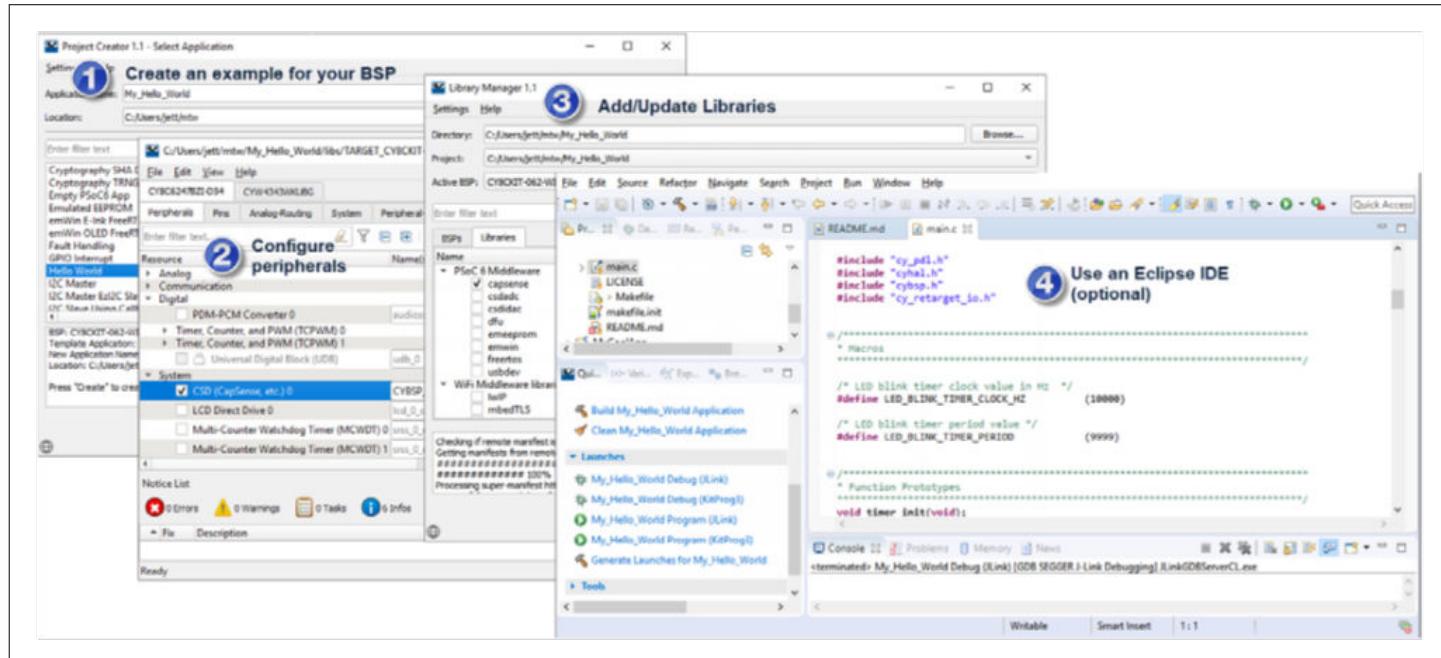


Figure 1 ModusToolbox™ software tools

1.3 PSoC™ Creator

[PSoC™ Creator](#) is a free Windows-based IDE. It enables you to design hardware and firmware systems concurrently, based on PSoC™ 4 MCU. As [Figure 2](#) shows, with PSoC™ Creator you can:

1. Explore the library of 200+ components
2. Drag and drop component icons to complete your hardware system design in the main design workspace
3. Configure components using the component configuration tools and the component datasheets
4. Co-design your application firmware and hardware in the PSoC™ Creator IDE or build a project for a third-party IDE
5. Prototype your solution with the PSoC™ 4 pioneer kits. If a design change is needed, PSoC™ Creator and components enable you to make changes on-the-fly without the need for hardware revisions

1 Development ecosystem

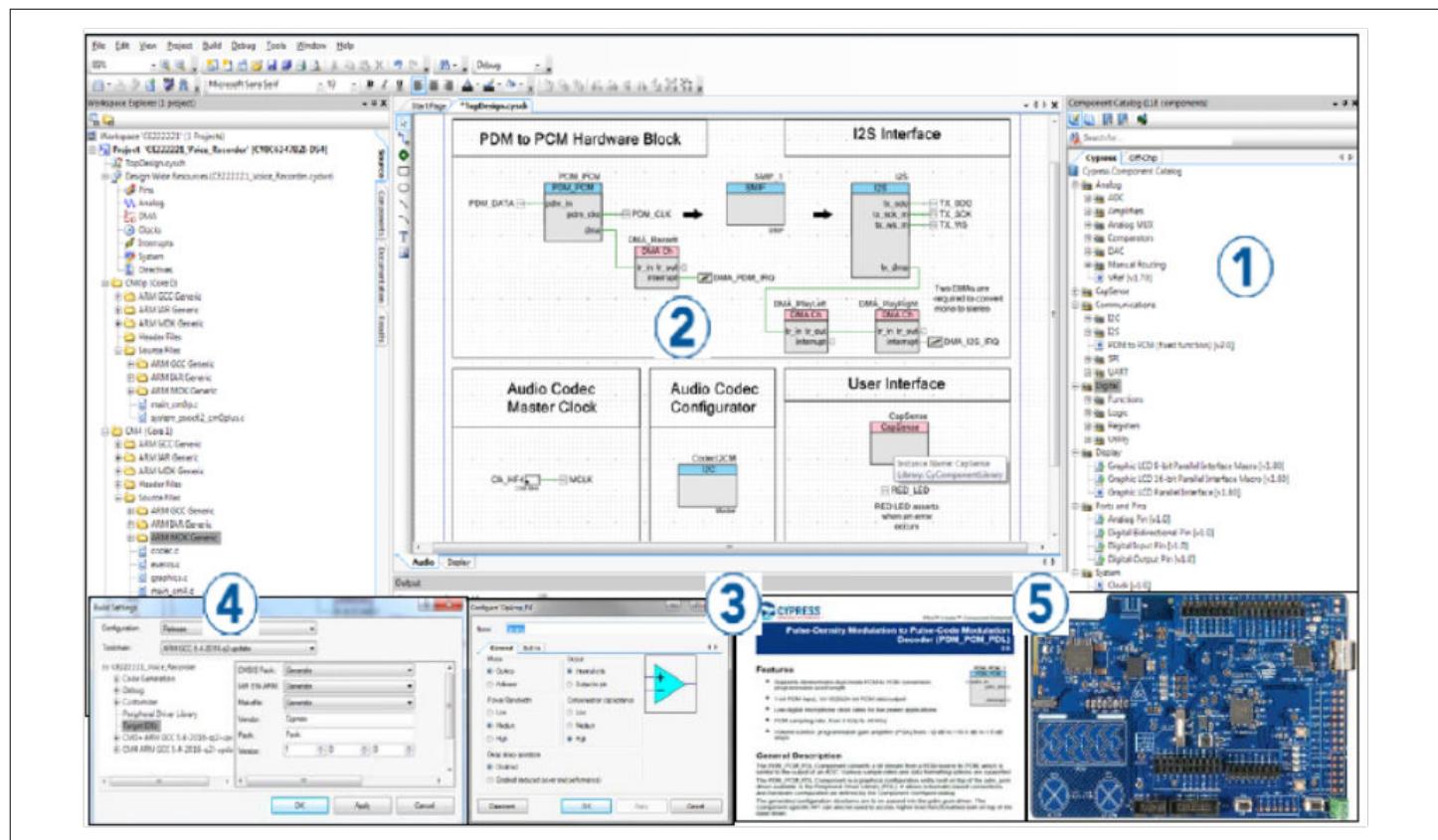


Figure 2 PSoC™ Creator schematic entry and components

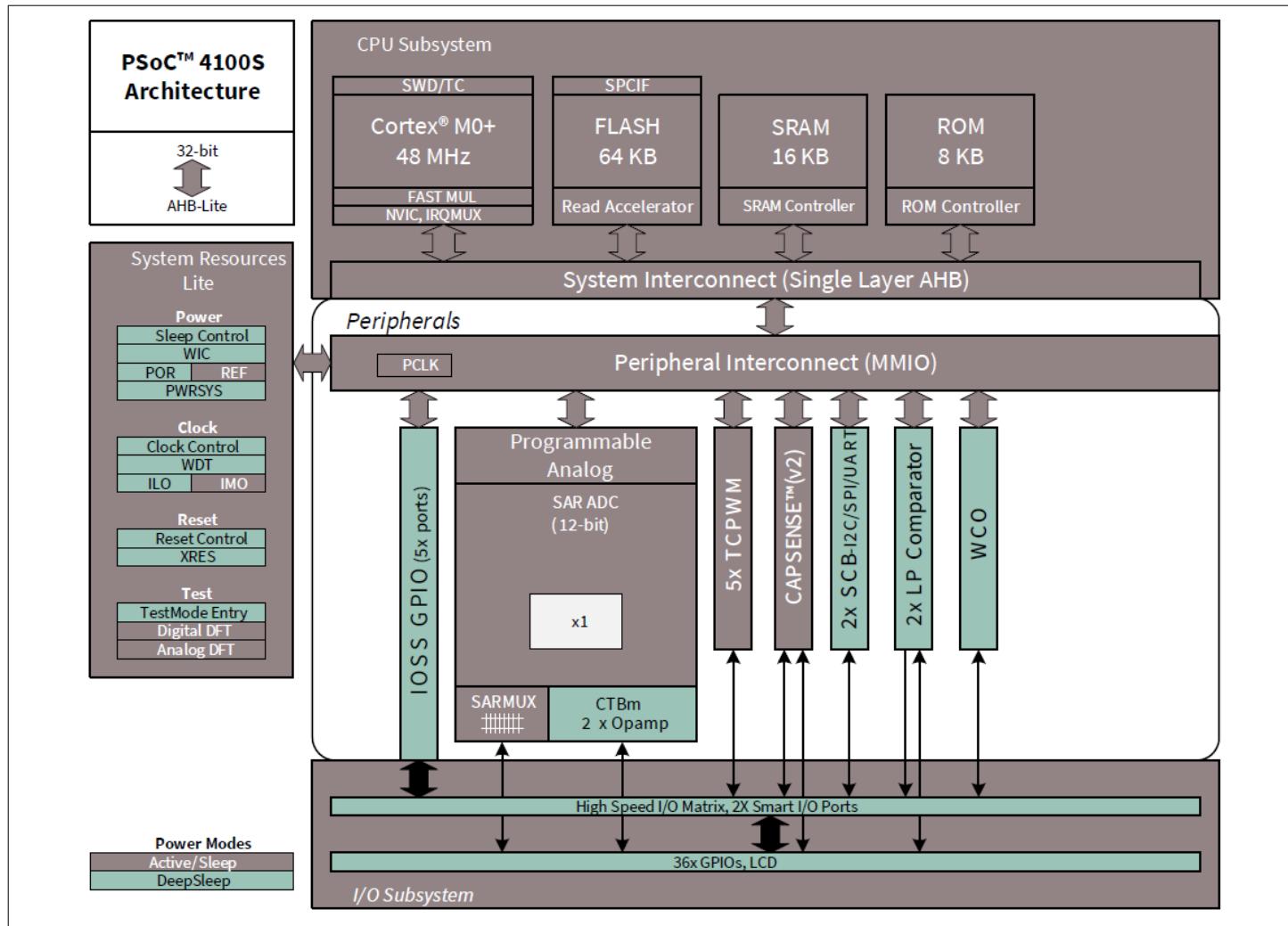


Figure 3 Block diagram

PSoC™ 4100S devices include extensive support for programming, testing, debugging, and tracing both hardware and firmware.

The Arm® serial-wire debug (SWD) interface supports all programming and debug features of the device.

Complete debug-on-chip functionality enables full-device debugging in the final system using the standard production device. It does not require special interfaces, debugging pods, simulators, or emulators. Only the standard programming connections are required to fully support debug.

The PSoC™ Creator IDE provides fully integrated programming and debug support for the PSoC™ 4100S devices. The SWD interface is fully compatible with industry-standard third-party tools. The PSoC™ 4100S provides a level of security not possible with multi-chip application solutions or with microcontrollers.

It has the following advantages:

- Allows disabling of debug features
- Robust flash protection
- Allows customer-proprietary functionality to be implemented in on-chip programmable blocks

The debug circuits are enabled by default and can be disabled in firmware. If they are not enabled, the only way to re-enable them is to erase the entire device, clear flash protection, and reprogram the device with new firmware that enables debugging. Thus firmware control of debugging cannot be over-ridden without erasing the firmware thus providing security.

Additionally, all device interfaces can be permanently disabled (device security) for applications concerned about phishing attacks due to a maliciously reprogrammed device or attempts to defeat security by starting and

interrupting flash programming sequences. All programming, debug, and test interfaces are disabled when maximum device security is enabled. Therefore, PSoC™ 4100S, with device security enabled, may not be returned for failure analysis. This is a trade-off the PSoC™ 4100S allows the customer to make.

2 Functional definition

2.1 CPU and memory subsystem

2.1.1 CPU

The Cortex®-M0+ CPU in the PSoC™ 4100S is part of the 32-bit MCU subsystem, which is optimized for low-power operation with extensive clock gating. Most instructions are 16 bits in length and the CPU executes a subset of the thumb-2 instruction set. It includes a nested vectored interrupt controller (NVIC) block with eight interrupt inputs and also includes a wakeup interrupt controller (WIC). The WIC can wake the processor from Deep Sleep mode, allowing power to be switched off to the main processor when the chip is in Deep Sleep mode.

The CPU also includes a debug interface, the serial wire debug (SWD) interface, which is a two-wire form of JTAG. The debug configuration used for PSoC™ 4100S has four breakpoint (address) comparators and two watchpoint (data) comparators.

2.1.2 Flash

The PSoC™ 4100S device has a flash module with a flash accelerator, tightly coupled to the CPU to improve average access times from the flash block. The low-power flash block is designed to deliver two wait-state (WS) access time at 48 MHz. The flash accelerator delivers 85% of single-cycle SRAM access performance on average.

2.1.3 SRAM

Eight KB of SRAM are provided with zero wait-state access at 48 MHz.

2.1.4 SROM

An 8 KB supervisory ROM that contains boot and configuration routines is provided.

2.2 System resources

2.2.1 Power system

The power system is described in detail in the section [Power](#). It provides assurance that voltage levels are as required for each respective mode and either delays mode entry (for example, on power-on reset (POR)) until voltage levels are as required for proper functionality, or generates resets (for example, on brown-out detection). The PSoC™ 4100S operates with a single external supply over the range of either 1.8 V ± 5% (externally regulated) or 1.8 to 5.5 V (internally regulated) and has three different power modes, transitions between which are managed by the power system. The PSoC™ 4100S provides Active, Sleep, and Deep Sleep low-power modes.

All subsystems are operational in Active mode. The CPU subsystem (CPU, flash, and SRAM) is clock-gated off in Sleep mode, while all peripherals and interrupts are active with instantaneous wake-up on a wake-up event. In Deep Sleep mode, the high-speed clock and associated circuitry is switched OFF; wake-up from this mode takes 35 µs. The opamps can remain operational in Deep Sleep mode.

2.2.2 Clock system

PSoC™ 4100S clock system is responsible for providing clocks to all subsystems that require clocks and for switching between different clock sources without glitching. In addition, the clock system ensures that there are no metastable conditions.

2 Functional definition

The clock system for the PSoC™ 4100S consists of the internal main oscillator (IMO), internal low-frequency oscillator (ILO), a 32 kHz watch crystal oscillator (WCO) and provision for an external clock. Clock dividers are provided to generate clocks for peripherals on a fine-grained basis. Fractional dividers are also provided to enable clocking of higher data rates for UARTs.

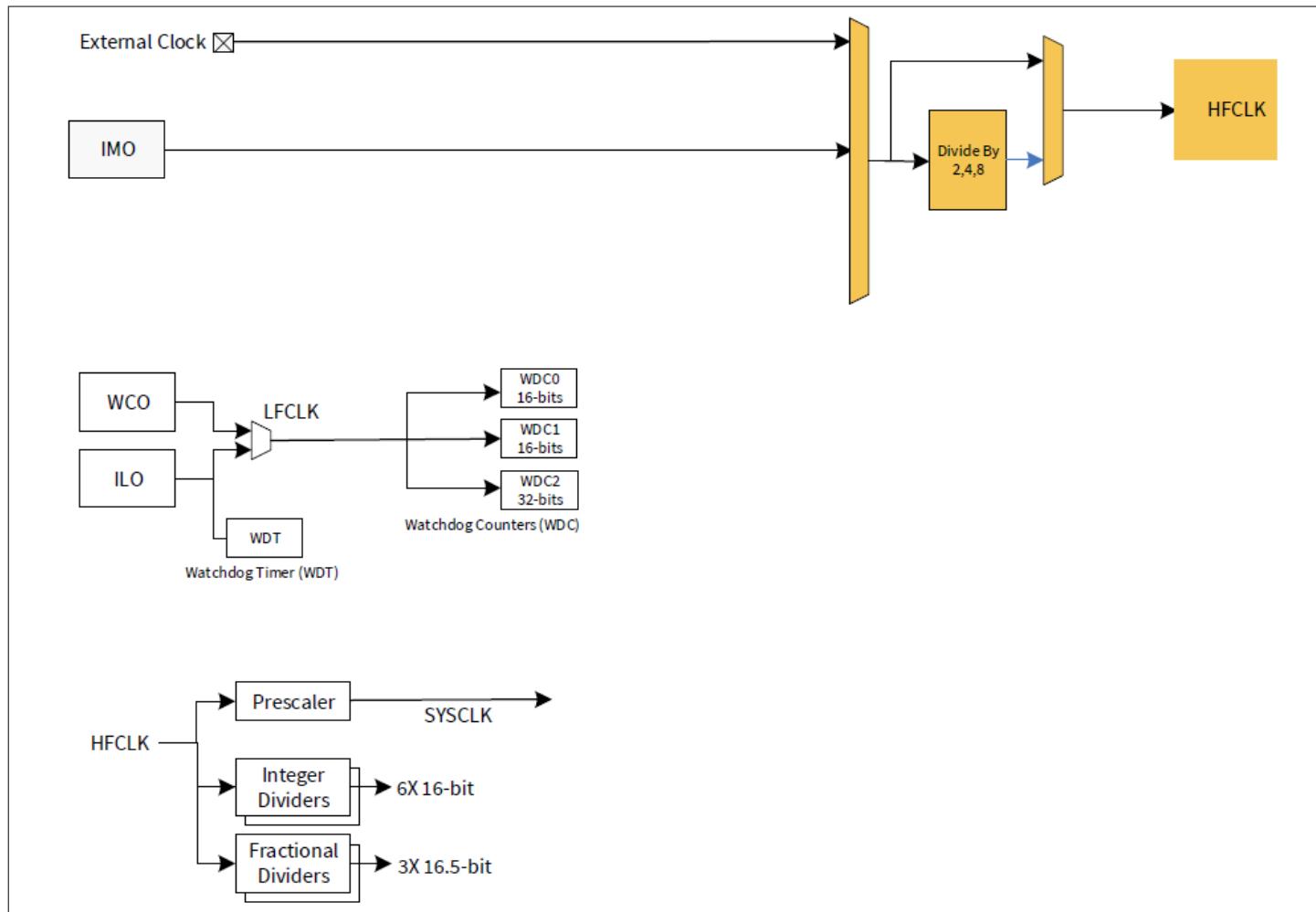


Figure 4 **PSoC™ 4100S MCU clocking architecture**

The HFCLK signal can be divided down to generate synchronous clocks for the analog and digital peripherals. There are eight clock dividers for the PSoC™ 4100S; two of those are fractional dividers. The 16-bit capability allows flexible generation of fine-grained frequency values and is fully supported in PSoC™ Creator.

2.2.3 IMO clock source

The IMO is the primary source of internal clocking in the PSoC™ 4100S. It is trimmed during testing to achieve the specified accuracy. The IMO default frequency is 24 MHz and it can be adjusted from 24 to 48 MHz in steps of 4 MHz. The IMO tolerance with Infineon provided calibration settings is $\pm 2\%$.

2.2.4 ILO clock source

The ILO is a very low power, nominally 40-kHz oscillator, which is primarily used to generate clocks for the watchdog timer (WDT) and peripheral operation in Deep Sleep mode. ILO-driven counters can be calibrated to the IMO to improve accuracy. Infineon provides a software component, which does the calibration.

2.2.5 Watch crystal oscillator (WCO)

The PSoC™ 4100S clock subsystem also implements a low-frequency (32 kHz watch crystal) oscillator that can be used for precision timing applications. The WCO block allows locking the IMO to the 32 kHz oscillator.

2.2.6 Watchdog timer and counters

A watchdog timer is implemented in the clock block running from the ILO; this allows watchdog operation during Deep Sleep and generates a watchdog reset if not serviced before the set timeout occurs. The watchdog reset is recorded in a Reset Cause Register, which is firmware readable. The watchdog counters can be used to implement a real-time clock using the 32-kHz WCO.

2.2.7 Reset

The PSoC™ 4100S can be reset from a variety of sources including a software reset. Reset events are asynchronous and guarantee reversion to a known state. The reset cause is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES pin is reserved for external reset by asserting it active low. The XRES pin has an internal pull-up resistor that is always enabled.

2.3 Analog blocks

2.3.1 12-bit SAR ADC

The 12-bit, 1-MspS SAR ADC can operate at a maximum clock rate of 18 MHz and requires a minimum of 18 clocks at that frequency to do a 12-bit conversion.

The sample-and-hold (S/H) aperture is programmable allowing the gain bandwidth requirements of the amplifier driving the SAR inputs, which determine its settling time, to be relaxed if required. It is possible to provide an external bypass (through a fixed pin location) for the internal reference amplifier.

The SAR is connected to a fixed set of pins through an 8-input sequencer. The sequencer cycles through selected channels autonomously (sequencer scan) with zero switching overhead (that is, aggregate sampling bandwidth is equal to 1 MspS whether it is for a single channel or distributed over several channels). The sequencer switching is effected through a state machine or through firmware driven switching. A feature provided by the sequencer is buffering of each channel to reduce CPU interrupt service requirements. To accommodate signals with varying source impedance and frequency, it is possible to have different sample times programmable for each channel. Also, signal range specification through a pair of range registers (low and high range values) is implemented with a corresponding out-of-range interrupt if the digitized value exceeds the programmed range; this allows fast detection of out-of-range values without the necessity of having to wait for a sequencer scan to be completed and the CPU to read the values and check for out-of-range values in software.

The SAR is not available in Deep Sleep mode as it requires a high-speed clock (up to 18 MHz). The SAR operating range is 1.71 V to 5.5 V.

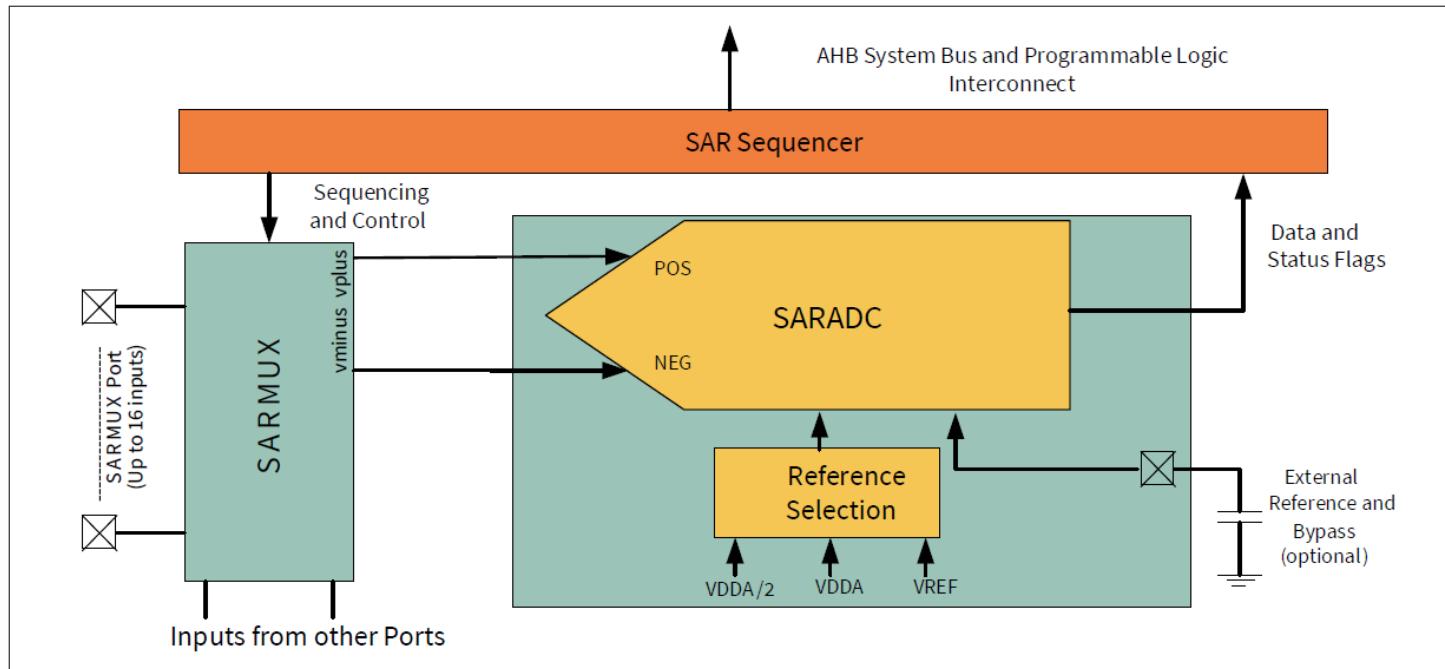


Figure 5 SAR ADC

2.3.2 Two opamps (continuous-time block; CTB)

The PSoC™ 4100S has two opamps with Comparator modes which allow most common analog functions to be performed on-chip eliminating external components; PGAs, Voltage Buffers, Filters, Trans-Impedance Amplifiers, and other functions can be realized, in some cases with external passives. saving power, cost, and space. The on-chip opamps are designed with enough bandwidth to drive the Sample-and-Hold circuit of the ADC without requiring external buffering.

2.3.3 Low-power comparators (LPC)

The PSoC™ 4100S has a pair of low-power comparators, which can also operate in Deep Sleep modes. This allows the analog system blocks to be disabled while retaining the ability to monitor external voltage levels during low-power modes. The comparator outputs are normally synchronized to avoid metastability unless operating in an asynchronous power mode where the system wake-up circuit is activated by a comparator switch event. The LPC outputs can be routed to pins.

2.3.4 Current DACs

The PSoC™ 4100S has two IDACs, which can drive any of the pins on the chip. These IDACs have programmable current ranges.

2.3.5 Analog multiplexed buses

The PSoC™ 4100S has two concentric independent buses that go around the periphery of the chip. These buses (called amux buses) are connected to firmware-programmable analog switches that allow the chip's internal resources (IDACs, comparator) to connect to any pin on the I/O ports.

2.4 Programmable digital blocks

The smart I/O block is a fabric of switches and LUTs that allows boolean functions to be performed in signals being routed to the pins of a GPIO port. The Smart I/O can perform logical operations on input pins to the chip and on signals going out as outputs.

2.5 Fixed function digital

2.5.1 Timer/Counter/PWM (TCPWM) block

The TCPWM block consists of a 16-bit counter with user-programmable period length. There is a capture register to record the count value at the time of an event (which may be an I/O event), a period register that is used to either stop or auto-reload the counter when its count is equal to the period register, and compare registers to generate compare value signals that are used as PWM duty cycle outputs. The block also provides true and complementary outputs with programmable offset between them to allow use as dead-band programmable complementary PWM outputs. It also has a kill input to force outputs to a predetermined state; for example, this is used in motor drive systems when an over-current state is indicated and the PWM driving the FETs needs to be shut off immediately with no time for software intervention. There are five TCPWM blocks in the PSoC™ 4100S.

2.5.2 Serial communication block (SCB)

The PSoC™ 4100S has three serial communication blocks, which can be programmed to have SPI, I2C, or UART functionality.

I²C Mode: The hardware I²C block implements a full multi-master and slave interface (it is capable of multi-master arbitration). This block is capable of operating at speeds of up to 400 kbps (Fast Mode) and has flexible buffering options to reduce interrupt overhead and latency for the CPU. It also supports EZI2C that creates a mailbox address range in the memory of the PSoC™ 4100S and effectively reduces I²C communication to reading from and writing to an array in memory. In addition, the block supports an 8-deep FIFO for receive and transmit which, by increasing the time given for the CPU to read data, greatly reduces the need for clock stretching caused by the CPU not having read data on time.

The I²C peripheral is compatible with the I²C Standard-mode and Fast-mode devices as defined in the NXP I²C-bus specification and user manual (UM10204). The I²C bus I/O is implemented with GPIO in open-drain modes.

The PSoC™ 4100S is not completely compliant with the I²C spec in the following respect:

- GPIO cells are not over-voltage tolerant and, therefore, cannot be hot-swapped or powered up independently of the rest of the I²C system.

UART Mode: This is a full-feature UART operating at up to 1 Mbps. It supports automotive single-wire interface (LIN), infrared interface (IrDA), and SmartCard (ISO7816) protocols, all of which are minor variants of the basic UART protocol. In addition, it supports the 9-bit multiprocessor mode that allows addressing of peripherals connected over common RX and TX lines. Common UART functions such as parity error, break detect, and frame error are supported. An 8-deep FIFO allows much greater CPU service latencies to be tolerated.

SPI Mode: The SPI mode supports full Motorola SPI, TI SSP (adds a start pulse used to synchronize SPI Codecs), and National Microwire (half-duplex form of SPI). The SPI block can use the FIFO.

2.6 GPIO

The PSoC™ 4100S has up to 36 GPIOs. The GPIO block implements the following:

- Eight drive modes:
 - Analog input mode (input and output buffers disabled)
 - Input only
 - Weak pull-up with strong pull-down

2 Functional definition

- Strong pull-up with weak pull-down
- Open drain with strong pull-down
- Open drain with strong pull-up
- Strong pull-up with strong pull-down
- Weak pull-up with weak pull-down
- Input threshold select (CMOS or LVTTL).
- Individual control of input and output buffer enabling/disabling in addition to the drive strength modes
- Selectable slew rates for dV/dt related noise control to improve EMI

The pins are organized in logical entities called ports, which are 8-bit in width (less for ports 2 and 3). During power-on and reset, the blocks are forced to the disable state so as not to crowbar any inputs and/or cause excess turn-on current. A multiplexing network known as a high-speed I/O matrix is used to multiplex between various signals that may connect to an I/O pin.

Data output and pin state registers store, respectively, the values to be driven on the pins and the states of the pins themselves.

Every I/O pin can generate an interrupt if so enabled and each I/O port has an interrupt request (IRQ) and interrupt service routine (ISR) vector associated with it (5 for PSoC™ 4100S).

2.7 Special function peripherals

2.7.1 CAPSENSE™

CAPSENSE™ is supported in the PSoC™ 4100S through a CAPSENSE™ Sigma-Delta (CSD) block that can be connected to any pins through an analog multiplex bus via analog switches. CAPSENSE™ function can thus be provided on any available pin or group of pins in a system under software control. A PSoC™ Creator component is provided for the CAPSENSE™ block to make it easy for the user.

Shield voltage can be driven on another analog multiplex bus to provide water-tolerance capability. Water tolerance is provided by driving the shield electrode in phase with the sense electrode to keep the shield capacitance from attenuating the sensed input. Proximity sensing can also be implemented.

The CAPSENSE™ block has two IDACs, which can be used for general purposes if CAPSENSE™ is not being used (both IDACs are available in that case) or if CAPSENSE™ is used without water tolerance (one IDAC is available).

The CAPSENSE™ block also provides a 10-bit slope ADC function which can be used in conjunction with the CAPSENSE™ function.

The CAPSENSE™ block is an advanced, low-noise, programmable block with programmable voltage references and current source ranges for improved sensitivity and flexibility. It can also use an external reference voltage. It has a full-wave CSD mode that alternates sensing to VDDA and ground to null out power-supply related noise.

2.7.2 LCD segment drive

The PSoC™ 4100S has an LCD controller, which can drive up to 4 commons and up to 32 segments. It uses full digital methods to drive the LCD segments requiring no generation of internal LCD voltages. The two methods used are referred to as digital correlation and PWM. Digital correlation pertains to modulating the frequency and drive levels of the common and segment signals to generate the highest RMS voltage across a segment to light it up or to keep the RMS signal to zero. This method is good for STN displays but may result in reduced contrast with TN (cheaper) displays. PWM pertains to driving the panel with PWM signals to effectively use the capacitance of the panel to provide the integration of the modulated pulse-width to generate the desired LCD voltage. This method results in higher power consumption but can result in better results when driving TN displays. LCD operation is supported during Deep Sleep refreshing a small display buffer (4 bits; 1 32-bit register per port).

3 Pinouts

Table 1 provides the pin list for PSoC™ 4100S for the 48LD TQFP, 44LD TQFP, 40L QFN, 32-lead QFN, and 35-ball WLCSP packages. All port pins support GPIO.

Table 1 Pin list

| 48LD TQFP | | 44LD TQFP | | 40L QFN | | 32-lead QFN | | 35-ball WLCSP | |
|-----------|-----------|-----------|-----------|---------|-----------|-------------|-----------|---------------|-----------|
| Pin | Name | Pin | Name | Pin | Name | Pin | Name | Pin | Name |
| 1 | P1.7/VREF | 44 | P1.7/VREF | 40 | P1.7/VREF | 1 | P1.7/VREF | E7 | P1.7/VREF |
| | | 1 | VSSD | | | | | | |
| 2 | P2.0 | 2 | P2.0 | 1 | P2.0 | 2 | P2.0 | | |
| 3 | P2.1 | 3 | P2.1 | 2 | P2.1 | 3 | P2.1 | | |
| 4 | P2.2 | 4 | P2.2 | 3 | P2.2 | 4 | P2.2 | D3 | P2.2 |
| 5 | P2.3 | 5 | P2.3 | 4 | P2.3 | 5 | P2.3 | E4 | P2.3 |
| 6 | P2.4 | 6 | P2.4 | 5 | P2.4 | | | E5 | P2.4 |
| 7 | P2.5 | 7 | P2.5 | 6 | P2.5 | 6 | P2.5 | E6 | P2.5 |
| 8 | P2.6 | 8 | P2.6 | 7 | P2.6 | 7 | P2.6 | E3 | P2.6 |
| 9 | P2.7 | 9 | P2.7 | 8 | P2.7 | 8 | P2.7 | E2 | P2.7 |
| 10 | VSSD | 10 | VSSD | 9 | VSSD | | | | |
| 12 | P3.0 | 11 | P3.0 | 10 | P3.0 | 9 | P3.0 | E1 | P3.0 |
| 13 | P3.1 | 12 | P3.1 | 11 | P3.1 | 10 | P3.1 | D2 | P3.1 |
| 14 | P3.2 | 13 | P3.2 | 12 | P3.2 | 11 | P3.2 | D1 | P3.2 |
| 16 | P3.3 | 14 | P3.3 | 13 | P3.3 | 12 | P3.3 | C1 | P3.3 |
| 17 | P3.4 | 15 | P3.4 | 14 | P3.4 | | | C2 | P3.4 |
| 18 | P3.5 | 16 | P3.5 | 15 | P3.5 | | | | |
| 19 | P3.6 | 17 | P3.6 | 16 | P3.6 | | | | |
| 20 | P3.7 | 18 | P3.7 | 17 | P3.7 | | | | |
| 21 | VDDD | 19 | VDDD | | | | | | |
| 22 | P4.0 | 20 | P4.0 | 18 | P4.0 | 13 | P4.0 | B1 | P4.0 |
| 23 | P4.1 | 21 | P4.1 | 19 | P4.1 | 14 | P4.1 | B2 | P4.1 |
| 24 | P4.2 | 22 | P4.2 | 20 | P4.2 | 15 | P4.2 | A2 | P4.2 |
| 25 | P4.3 | 23 | P4.3 | 21 | P4.3 | 16 | P4.3 | A1 | P4.3 |
| 28 | P0.0 | 24 | P0.0 | 22 | P0.0 | 17 | P0.0 | C3 | P0.0 |
| 29 | P0.1 | 25 | P0.1 | 23 | P0.1 | 18 | P0.1 | A5 | P0.1 |
| 30 | P0.2 | 26 | P0.2 | 24 | P0.2 | 19 | P0.2 | A4 | P0.2 |
| 31 | P0.3 | 27 | P0.3 | 25 | P0.3 | 20 | P0.3 | A3 | P0.3 |
| 32 | P0.4 | 28 | P0.4 | 26 | P0.4 | 21 | P0.4 | B3 | P0.4 |
| 33 | P0.5 | 29 | P0.5 | 27 | P0.5 | 22 | P0.5 | A6 | P0.5 |

(table continues...)

Table 1 (continued) Pin list

| 48LD TQFP | | 44LD TQFP | | 40L QFN | | 32-lead QFN | | 35-ball WLCSP | |
|-----------|------|-----------|------|---------|------|-------------|------|---------------|------|
| Pin | Name | Pin | Name | Pin | Name | Pin | Name | Pin | Name |
| 34 | P0.6 | 30 | P0.6 | 28 | P0.6 | 23 | P0.6 | B4 | P0.6 |
| 35 | P0.7 | 31 | P0.7 | 29 | P0.7 | | | B5 | P0.7 |
| 36 | XRES | 32 | XRES | 30 | XRES | 24 | XRES | B6 | XRES |
| 37 | VCCD | 33 | VCCD | 31 | VCCD | 25 | VCCD | A7 | VCCD |
| 38 | VSSD | | | | | 26 | VSSD | B7 | VSS |
| 39 | VDDD | 34 | VDDD | 32 | VDDD | | | C7 | VDD |
| 40 | VDDA | 35 | VDDA | 33 | VDDA | 27 | VDD | C7 | VDD |
| 41 | VSSA | 36 | VSSA | 34 | VSSA | 28 | VSSA | B7 | VSS |
| 42 | P1.0 | 37 | P1.0 | 35 | P1.0 | 29 | P1.0 | C4 | P1.0 |
| 43 | P1.1 | 38 | P1.1 | 36 | P1.1 | 30 | P1.1 | C5 | P1.1 |
| 44 | P1.2 | 39 | P1.2 | 37 | P1.2 | 31 | P1.2 | C6 | P1.2 |
| 45 | P1.3 | 40 | P1.3 | 38 | P1.3 | 32 | P1.3 | D7 | P1.3 |
| 46 | P1.4 | 41 | P1.4 | 39 | P1.4 | | | D4 | P1.4 |
| 47 | P1.5 | 42 | P1.5 | | | | | D5 | P1.5 |
| 48 | P1.6 | 43 | P1.6 | | | | | D6 | P1.6 |

Note Pins 11, 15, 26, and 27 are No Connects (NC) on the 48LD TQFP.

Descriptions of the power pins are as follows:

VDDD: Power supply for the digital section.

VDDA: Power supply for the analog section.

VSSD, VSSA: Ground pins for the digital and analog sections respectively.

VCCD: Regulated digital supply ($1.8\text{ V} \pm 5\%$)

VDD: Power supply to all sections of the chip

VSS: Ground for all sections of the chip

3.1 Alternate pin functions

Each port pin can be assigned to one of multiple functions; it can, for instance, be an analog I/O, a digital peripheral function, an LCD pin, or a CAPSENSE™ pin. The pin assignments are shown in [Table 2](#).

Table 2 Alternate pin functions

| Port/ Pin | Analog | Smart I/O | Alternate function 1 | Alternate function 2 | Alternate function 3 | Deep Sleep 1 | Deep Sleep 2 |
|--------------|----------------|-----------|-------------------------|-------------------------|-------------------------|-------------------|-----------------------|
| P0.0 | lpcomp.in_p[0] | | | | tcpwm.tr_in[0] | scb[2].i2c_scl:0 | scb[0].spi_sele ct1:0 |
| P0.1 | lpcomp.in_n[0] | | | | tcpwm.tr_in[1] | scb[2].i2c_sda :0 | scb[0].spi_sele ct2:0 |

(table continues...)

Table 2 (continued) Alternate pin functions

| Port/ Pin | Analog | Smart I/O | Alternate function 1 | Alternate function 2 | Alternate function 3 | Deep Sleep 1 | Deep Sleep 2 |
|----------------------|---|------------------|---------------------------------|---------------------------------|---------------------------------|---------------------|-----------------------|
| P0.2 | lpcomp.in_p[1] | | | | | | scb[0].spi_sele ct3:0 |
| P0.3 | lpcomp.in_n[1] | | | | | | scb[2].spi_sele ct0 |
| P0.4 | wco.wco_i n | | | scb[1].uart_rx: 0 | scb[2].uart_rx: 0 | scb[1].i2c_scl: 0 | scb[1].spi_mosi:1 |
| P0.5 | wco.wco_o ut | | | scb[1].uart_tx: 0 | scb[2].uart_tx: 0 | scb[1].i2c_sda :0 | scb[1].spi_miso:1 |
| P0.6 | | srss.ext_clk | | scb[1].uart_ct s:0 | scb[2].uart_tx: 1 | | scb[1].spi_clk:1 |
| P0.7 | | tcpwm.line[0]:2 | | scb[1].uart_rts :0 | | | scb[1].spi_sele ct0:1 |
| P1.0 | ctb0_oa0+ | | tcpwm.line[2]:1 | scb[0].uart_rx: 1 | | scb[0].i2c_scl: 0 | scb[0].spi_mosi:1 |
| P1.1 | ctb0_oa0- | | tcpwm.line_com pl[2]:1 | scb[0].uart_tx: 1 | | scb[0].i2c_sda :0 | scb[0].spi_miso:1 |
| P1.2 | ctb0_oa0_ out | | tcpwm.line[3]:1 | scb[0].uart_ct s:1 | tcpwm.tr_in[2] | scb[2].i2c_scl: 1 | scb[0].spi_clk:1 |
| P1.3 | ctb0_oa1_ out | | tcpwm.line_com pl[3]:1 | scb[0].uart_rts :1 | tcpwm.tr_in[3] | scb[2].i2c_sda :1 | scb[0].spi_sele ct0:1 |
| P1.4 | ctb0_oa1- | | | | | | scb[0].spi_sele ct1:1 |
| P1.5 | ctb0_oa1+ | | | | | | scb[0].spi_sele ct2:1 |
| P1.6 | ctb0_oa0+ | | | | | | scb[0].spi_sele ct3:1 |
| P1.7 | ctb0_oa1+ sar_ext_vref0 sar_ext_vref1 | | | | | | scb[2].spi_clk |
| P2.0 | sarmux[0] | SmartIo[0].io[0] | tcpwm.line[4]:0 | csd.comp | tcpwm.tr_in[4] | scb[1].i2c_scl: 1 | scb[1].spi_mosi:2 |
| P2.1 | sarmux[1] | SmartIo[0].io[1] | tcpwm.line_com pl[4]:0 | | tcpwm.tr_in[5] | scb[1].i2c_sda :1 | scb[1].spi_miso:2 |
| P2.2 | sarmux[2] | SmartIo[0].io[2] | | | | | scb[1].spi_clk:2 |
| P2.3 | sarmux[3] | SmartIo[0].io[3] | | | | | scb[1].spi_sele ct0:2 |

(table continues...)

Table 2 (continued) Alternate pin functions

| Port/ Pin | Analog | Smart I/O | Alternate function 1 | Alternate function 2 | Alternate function 3 | Deep Sleep 1 | Deep Sleep 2 |
|----------------------|------------------|------------------|---------------------------------|---------------------------------|---------------------------------|---------------------|-----------------------|
| P2.4 | sarmux[4] | Smartlo[0].io[4] | tcpwm.line[0]:1 | | | | scb[1].spi_sele ct1:1 |
| P2.5 | sarmux[5] | Smartlo[0].io[5] | tcpwm.line_com pl[0]:1 | | | | scb[1].spi_sele ct2:1 |
| P2.6 | sarmux[6] | Smartlo[0].io[6] | tcpwm.line[1]:1 | | | | scb[1].spi_sele ct3:1 |
| P2.7 | sarmux[7] | Smartlo[0].io[7] | tcpwm.line_com pl[1]:1 | | | lpcomp.comp[0]:1 | scb[2].spi_mosi |
| P3.0 | | Smartlo[1].io[0] | tcpwm.line[0]:0 | scb[1].uart_rx:1 | | scb[1].i2c_scl:2 | scb[1].spi_mosi:0 |
| P3.1 | | Smartlo[1].io[1] | tcpwm.line_com pl[0]:0 | scb[1].uart_tx:1 | | scb[1].i2c_sda:2 | scb[1].spi_miso:0 |
| P3.2 | | Smartlo[1].io[2] | tcpwm.line[1]:0 | scb[1].uart_cts:1 | | cpuss.swd_da ta | scb[1].spi_clk:0 |
| P3.3 | | Smartlo[1].io[3] | tcpwm.line_com pl[1]:0 | scb[1].uart_rts:1 | | cpuss.swd_clk | scb[1].spi_sele ct0:0 |
| P3.4 | | Smartlo[1].io[4] | tcpwm.line[2]:0 | | tcpwm.tr_in[6] | | scb[1].spi_sele ct1:0 |
| P3.5 | | Smartlo[1].io[5] | tcpwm.line_com pl[2]:0 | | | | scb[1].spi_sele ct2:0 |
| P3.6 | | Smartlo[1].io[6] | tcpwm.line[3]:0 | | | | scb[1].spi_sele ct3:0 |
| P3.7 | | Smartlo[1].io[7] | tcpwm.line_com pl[3]:0 | | | lpcomp.comp[1]:1 | scb[2].spi_miso |
| P4.0 | csd.vref_ex t | | | scb[0].uart_rx:0 | | scb[0].i2c_scl:1 | scb[0].spi_mosi:0 |
| P4.1 | csd.cshield pads | | | scb[0].uart_tx:0 | | scb[0].i2c_sda:1 | scb[0].spi_miso:0 |
| P4.2 | csd.cmopdp ad | | | scb[0].uart_cts:0 | | lpcomp.comp[0]:0 | scb[0].spi_clk:0 |
| P4.3 | csd.csh_tank | | | scb[0].uart_rts:0 | | lpcomp.comp[1]:0 | scb[0].spi_sele ct0:0 |

4 Power

The following power system diagram shows the set of power supply pins as implemented for the PSoC™ 4100S. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the V_{DD} input.

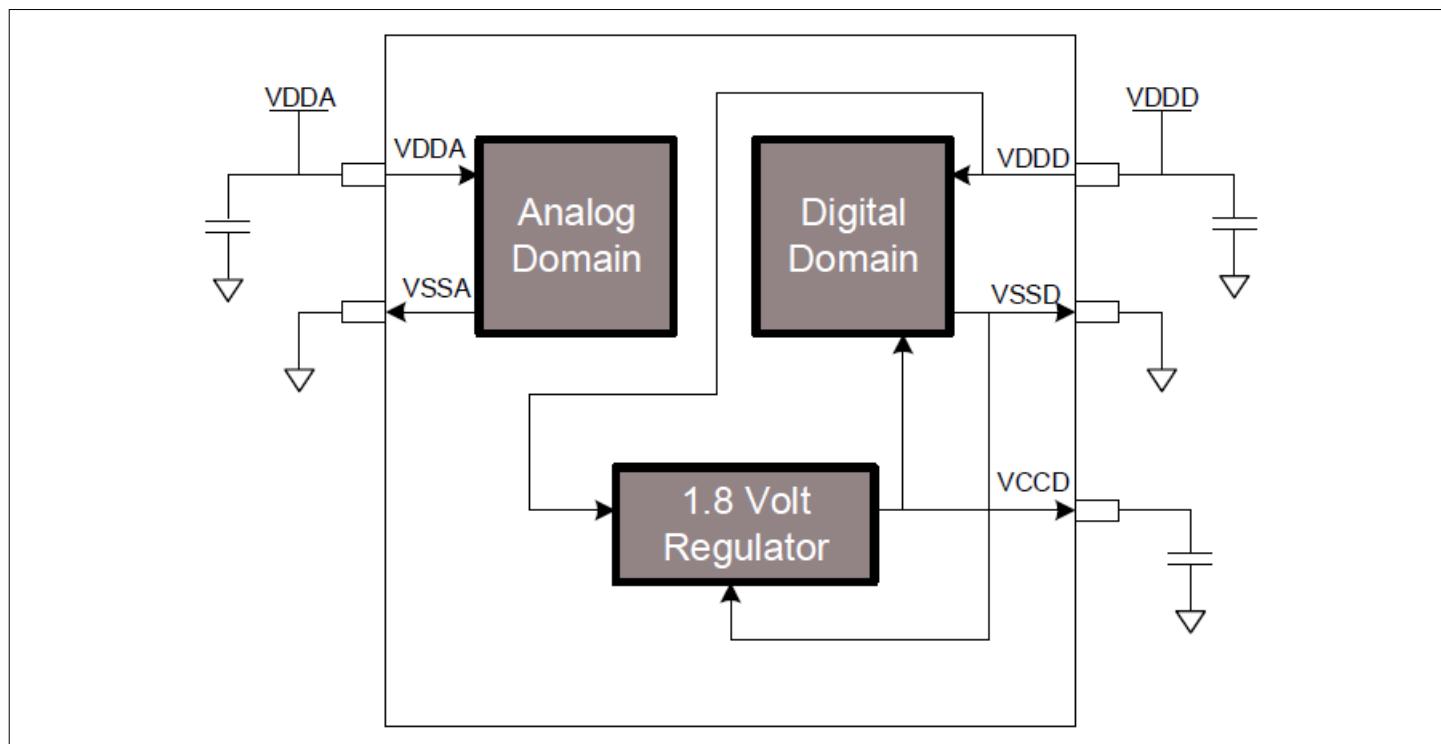


Figure 6 Power supply connections

There are two distinct modes of operation. In Mode 1, the supply voltage range is 1.8 V to 5.5 V (unregulated externally; internal regulator operational). In Mode 2, the supply range is 1.8 V ± 5% (externally regulated; 1.71 V to 1.89 V, internal regulator bypassed).

4.1 Mode 1: 1.8 V to 5.5 V external supply

In this mode, the PSoC™ 4100S is powered by an external power supply that can be anywhere in the range of 1.8 V to 5.5 V. This range is also designed for battery-powered operation. For example, the chip can be powered from a battery system that starts at 3.5 V and works down to 1.8 V. In this mode, the internal regulator of the PSoC™ 4100S supplies the internal logic and its output is connected to the V_{CCD} pin. The V_{CCD} pin must be bypassed to ground via an external capacitor (0.1 µF; X5R ceramic or better) and must not be connected to anything else.

4.2 Mode 2: 1.8 V ± 5% external supply

In this mode, the PSoC™ 4100S is powered by an external power supply that must be within the range of 1.71 V to 1.89 V; note that this range needs to include the power supply ripple too. In this mode, the V_{DD} and V_{CCD} pins are shorted together and bypassed. The internal regulator can be disabled in the firmware.

Bypass capacitors must be used from V_{DDD} to ground. The typical practice for systems in this frequency range is to use a capacitor in the 1-µF range, in parallel with a smaller capacitor (0.1 µF, for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

Figure 7 shows an example of a bypass scheme.

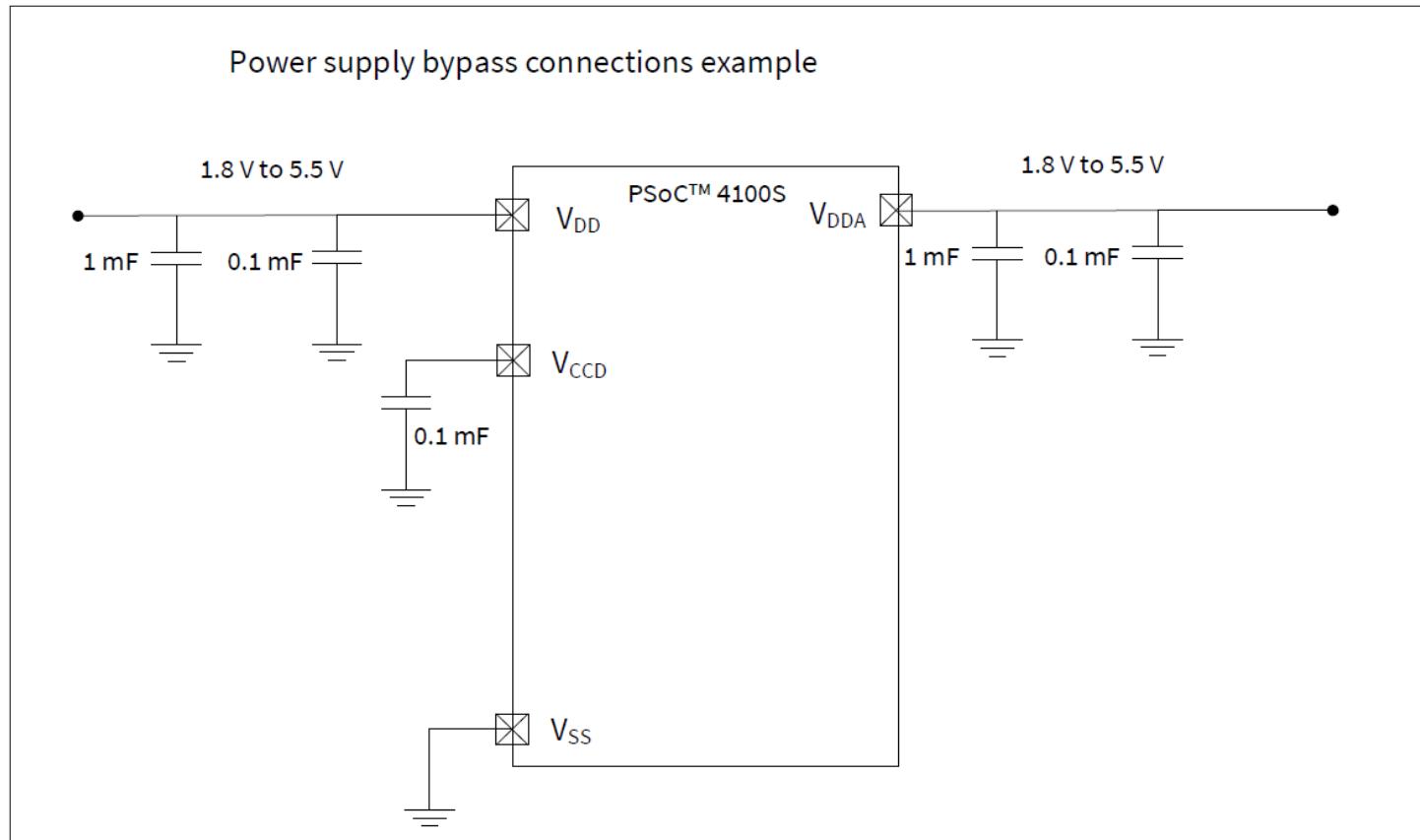


Figure 7

External supply range from 1.8 V to 5.5 V with internal regulator active

5 Electrical specifications

5 Electrical specifications

5.1 Absolute maximum ratings

Table 3 Absolute maximum ratings¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------------------------|---|------|-----|-----------------------|------|--------------------------|
| SID1 | V _{DDD_ABS} | Digital supply relative to V _{SS} | -0.5 | – | 6 | V | – |
| SID2 | V _{CCD_ABS} | Direct digital core voltage input relative to V _{SS} | -0.5 | – | 1.95 | | – |
| SID3 | V _{GPIO_ABS} | GPIO voltage | -0.5 | – | V _{DD} + 0.5 | | – |
| SID4 | I _{GPIO_ABS} | Maximum current per GPIO | -25 | – | 25 | mA | – |
| SID5 | I _{GPIO_injection} | GPIO injection current, Max for V _{IH} > V _{DD} , and Min for V _{IL} < V _{SS} | -0.5 | – | 0.5 | | Current injected per pin |
| BID44 | ESD_HBM | Electrostatic discharge human body model | 2200 | – | – | V | – |
| BID45 | ESD_CDM | Electrostatic discharge charged device model | 500 | – | – | | – |
| BID46 | LU | Pin current for latch-up | -140 | – | 140 | mA | – |

1) Usage above the absolute maximum conditions listed in Table 3 may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods of time may affect device reliability. The maximum storage temperature is 150°C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below absolute maximum conditions but above normal operating conditions, the device may not operate to specification.

5.2 Device level specifications

All specifications are valid for $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$ and $T_J \leq 125^\circ\text{C}$, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

Table 4 DC specifications

Typical values measured at V_{DD} = 3.3 V and 25°C.

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|------------------|--|------|-----|------|------|-------------------------------|
| SID53 | V _{DD} | Power supply input voltage | 1.8 | – | 5.5 | V | Internally regulated supply |
| SID255 | V _{DD} | Power supply input voltage (V _{CCD} = V _{DDD} = V _{DDA}) | 1.71 | – | 1.89 | | Internally unregulated supply |
| SID54 | V _{CCD} | Output voltage (for core logic) | – | 1.8 | – | | – |
| SID55 | C _{EFC} | External regulator voltage bypass | – | 0.1 | – | μF | X5R ceramic or better |
| SID56 | C _{EXC} | Power supply bypass capacitor | – | 1 | – | | |

(table continues...)

5 Electrical specifications

Table 4 (continued) DC specifications

Typical values measured at $V_{DD} = 3.3$ V and 25°C.

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|--|------------|--------------------------------------|-----|-----|------|------|--------------------------|
| Active Mode, $V_{DD} = 1.8$ V to 5.5 V. Typical values measured at $V_{DD} = 3.3$ V and 25°C. | | | | | | | |
| SID10 | I_{DD5} | Execute from flash; CPU at 6 MHz | – | 1.8 | 2.7 | mA | Max is at 85°C and 5.5 V |
| SID16 | I_{DD8} | Execute from flash; CPU at 24 MHz | – | 3.0 | 4.75 | | |
| SID19 | I_{DD11} | Execute from flash; CPU at 48 MHz | – | 5.4 | 6.85 | | |

Sleep Mode, $V_{DDD} = 1.8$ V to 5.5 V (Regulator on)

| | | | | | | | |
|-------|-------|---|---|-----|-----|----|-----------------------------------|
| SID22 | IDD17 | I^2C wakeup WDT, and comparators on | – | 1.7 | 2.2 | mA | 6 MHz. Max is at 85°C and 5.5 V. |
| SID25 | IDD20 | I^2C wakeup, WDT, and comparators on. | – | 2.2 | 2.5 | | 12 MHz. Max is at 85°C and 5.5 V. |

Sleep Mode, $V_{DDD} = 1.71$ V to 1.89 V (Regulator bypassed)

| | | | | | | | |
|--------|--------|--|---|-----|-----|----|-----------------------------------|
| SID28 | IDD23 | I^2C wakeup, WDT, and comparators on | – | 0.7 | 0.9 | mA | 6 MHz. Max is at 85°C and 5.5 V. |
| SID28A | IDD23A | I^2C wakeup, WDT, and comparators on | – | 1 | 1.2 | | 12 MHz. Max is at 85°C and 5.5 V. |

Deep Sleep Mode, $V_{DD} = 1.8$ V to 3.6 V (Regulator on)

| | | | | | | | |
|-------|------------|--------------------------|---|-----|----|---------|---------------------------|
| SID31 | I_{DD26} | I^2C wakeup and WDT on | – | 2.5 | 60 | μA | Max is at 3.6 V and 85°C. |
|-------|------------|--------------------------|---|-----|----|---------|---------------------------|

Deep Sleep Mode, $V_{DD} = 3.6$ V to 5.5 V (Regulator on)

| | | | | | | | |
|-------|------------|--------------------------|---|-----|----|---------|---------------------------|
| SID34 | I_{DD29} | I^2C wakeup and WDT on | – | 2.5 | 60 | μA | Max is at 5.5 V and 85°C. |
|-------|------------|--------------------------|---|-----|----|---------|---------------------------|

Deep Sleep Mode, $V_{DD} = V_{CCD} = 1.71$ V to 1.89 V (Regulator bypassed)

| | | | | | | | |
|-------|------------|--------------------------|---|-----|----|---------|----------------------------|
| SID37 | I_{DD32} | I^2C wakeup and WDT on | – | 2.5 | 65 | μA | Max is at 1.89 V and 85°C. |
|-------|------------|--------------------------|---|-----|----|---------|----------------------------|

XRES Current

| | | | | | | | |
|--------|--------------|------------------------------------|---|---|---|----|---|
| SID307 | I_{DD_XR} | Supply current while XRES asserted | – | 2 | 5 | mA | – |
|--------|--------------|------------------------------------|---|---|---|----|---|

Table 5 AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------------------|-----------------|-----------------------------|-----|-----|-----|---------|-----------------------------|
| SID48 | F_{CPU} | CPU frequency | DC | – | 48 | MHz | $1.71 \leq V_{DD} \leq 5.5$ |
| SID49 ¹⁾ | T_{SLEEP} | Wakeup from Sleep mode | – | 0 | – | μs | – |
| SID50 ¹⁾ | $T_{DEEPSLEEP}$ | Wakeup from Deep Sleep mode | – | 35 | – | | |

1) Guaranteed by characterization.

5.2.1 GPIO

Table 6 **GPIO DC specifications**

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|-----------------------|------------------|---|-----------------------|-----|----------------------|------|---|
| SID57 | $V_{IH}^{(1)}$ | Input voltage high threshold | $0.7 \times V_{DDD}$ | - | - | V | CMOS Input |
| SID58 | V_{IL} | Input voltage low threshold | - | - | $0.3 \times V_{DDD}$ | - | - |
| SID241 | $V_{IH}^{(1)}$ | LVTTL input, $V_{DDD} < 2.7\text{ V}$ | $0.7 \times V_{DDD}$ | - | - | - | - |
| SID242 | V_{IL} | LVTTL input, $V_{DDD} < 2.7\text{ V}$ | - | - | $0.3 \times V_{DDD}$ | - | - |
| SID243 | $V_{IH}^{(1)}$ | LVTTL input, $V_{DDD} \geq 2.7\text{ V}$ | 2.0 | - | - | - | - |
| SID244 | V_{IL} | LVTTL input, $V_{DDD} \geq 2.7\text{ V}$ | - | - | 0.8 | - | - |
| SID59 | V_{OH} | Output voltage high level | $V_{DDD} - 0.6$ | - | - | - | $I_{OH} = 4\text{ mA}, V_{DDD} \geq 3\text{ V}$ |
| SID60 | V_{OH} | Output voltage high level | $V_{DDD} - 0.5$ | - | - | - | $I_{OH} = 1\text{ mA at } 1.8\text{ V } V_{DDD}$ |
| SID61 | V_{OL} | Output voltage low level | - | - | 0.6 | - | $I_{OL} = 4\text{ mA at } 1.8\text{ V } V_{DDD}$ |
| SID62 | V_{OL} | Output voltage low level | - | - | 0.6 | - | $I_{OL} = 10\text{ mA, } V_{DDD} \geq 3\text{ V}$ |
| SID62A | V_{OL} | Output voltage low level | - | - | 0.4 | - | $I_{OL} = 3\text{ mA, } V_{DDD} \geq 3\text{ V}$ |
| SID63 | R_{PULLUP} | Pull-up resistor | 3.5 | 5.6 | 8.5 | kΩ | - |
| SID64 | $R_{PULLDOWN}$ | Pull-down resistor | 3.5 | 5.6 | 8.5 | - | - |
| SID65 | I_{IL} | Input leakage current (absolute value) | - | - | 2 | nA | $25^\circ\text{C}, V_{DDD} = 3.0\text{ V}$ |
| SID66 | C_{IN} | Input capacitance | - | - | 7 | pF | - |
| SID67 ⁽²⁾ | V_{HYSTTL} | Input hysteresis LVTTL | 25 | 40 | - | mV | $V_{DDD} \geq 2.7\text{ V}$ |
| SID68 ⁽²⁾ | $V_{HYSCMOS}$ | Input hysteresis CMOS | $0.05 \times V_{DDD}$ | - | - | - | $V_{DD} < 4.5\text{ V}$ |
| SID68A ⁽²⁾ | $V_{HYSCMOSSV5}$ | Input hysteresis CMOS | 200 | - | - | - | - |
| SID69 ⁽²⁾ | I_{DIODE} | Current through protection diode to V_{DD}/V_{SS} | - | - | 100 | µA | - |
| SID69A ⁽²⁾ | I_{TOT_GPIO} | Maximum total source or sink chip current | - | - | 200 | mA | - |

1) V_{IH} must not exceed $V_{DDD} + 0.2\text{ V}$.

2) Guaranteed by characterization.

5 Electrical specifications

Table 7 GPIO AC specifications

(Guaranteed by characterization)

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------------------|---|-----|-----|------|------|---|
| SID70 | T _{RISEF} | Rise time in Fast strong mode | 2 | – | 12 | ns | 3.3 V V _{DDD} , Cload = 25 pF |
| SID71 | T _{FALLF} | Fall time in Fast strong mode | 2 | – | 12 | | |
| SID72 | T _{RISES} | Rise time in Slow strong mode | 10 | – | 60 | | |
| SID73 | T _{FALLS} | Fall time in Slow strong mode | 10 | – | 60 | | |
| SID74 | F _{GPIOOUT1} | GPIO F _{OUT} ; 3.3 V ≤ V _{DDD} ≤ 5.5 V Fast strong mode | – | – | 33 | MHz | 90/10%, 25 pF load, 60/40 duty cycle |
| SID75 | F _{GPIOOUT2} | GPIO F _{OUT} ; 1.71 V ≤ V _{DDD} ≤ 3.3 V Fast strong mode | – | – | 16.7 | | |
| SID76 | F _{GPIOOUT3} | GPIO F _{OUT} ; 3.3 V ≤ V _{DDD} ≤ 5.5 V Slow strong mode | – | – | 7 | | |
| SID245 | F _{GPIOOUT4} | GPIO F _{OUT} ; 1.71 V ≤ V _{DDD} ≤ 3.3 V Slow strong mode. | – | – | 3.5 | | |
| SID246 | F _{GPIOIN} | GPIO input operating frequency; 1.71 V ≤ V _{DDD} ≤ 5.5 V | – | – | 48 | | 90/10% V _{IO} |

5.2.2 XRES

Table 8 XRES DC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------------------|----------------------|--|------------------------|-----|------------------------|------|--|
| SID77 | V _{IH} | Input voltage high threshold | 0.7 × V _{DDD} | – | – | V | CMOS Input |
| SID78 | V _{IL} | Input voltage low threshold | – | – | 0.3 × V _{DDD} | | |
| SID79 | R _{PULLUP} | Pull-up resistor | – | 60 | – | kΩ | – |
| SID80 | C _{IN} | Input capacitance | – | – | 7 | pF | – |
| SID81 ¹⁾ | V _{HYSXRES} | Input voltage hysteresis | – | 100 | – | mV | Typical hysteresis is 200 mV for V _{DD} > 4.5 V |
| SID82 | I _{DIODE} | Current through protection diode to V _{DD} /V _{SS} | – | – | 100 | μA | – |

1) Guaranteed by characterization.

5 Electrical specifications

Table 9 XRES AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|------------------|---------------------------------|------------|------------|------------|---------------|---------------------------|
| SID83 ¹⁾ | $T_{RESETWIDTH}$ | Reset pulse width | 1 | - | - | μs | - |
| BID194 ¹⁾ | $T_{RESETWAKE}$ | Wake-up time from reset release | - | - | 2.7 | ms | - |

1) Guaranteed by characterization

5.3 Analog peripherals

5.3.1 CTBm Opamp

Table 10 CTBm Opamp specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|---------------------|---|------------|------------|------------|---------------|---|
| | I_{DD} | Opamp block current, external load | | | | | |
| SID269 | I_{DD_HI} | Power = High | - | 1100 | 1850 | μA | - |
| SID270 | I_{DD_MED} | Power = Medium | - | 550 | 950 | | - |
| SID271 | I_{DD_LOW} | Power = Low | - | 150 | 350 | | - |
| | G_{BW} | Load = 20 pF, 0.1 mA $V_{DDA} = 2.7 \text{ V}$ | | | | | |
| SID272 | G_{BW_HI} | Power = High | 6 | - | - | MHz | Input and output are 0.2 V to $V_{DDA} - 0.2 \text{ V}$ |
| SID273 | G_{BW_MED} | Power = Medium | 3 | - | - | | |
| SID274 | G_{BW_LO} | Power = Low | - | 1 | - | | |
| | I_{OUT_MAX} | $V_{DDA} = 2.7 \text{ V}$, 500 mV from rail | | | | | |
| SID275 | $I_{OUT_MAX_HI}$ | Power = High | 10 | - | - | mA | Output is 0.5 V to $V_{DDA} - 0.5 \text{ V}$ |
| SID276 | $I_{OUT_MAX_MID}$ | Power = Medium | 10 | - | - | | |
| SID277 | $I_{OUT_MAX_LO}$ | Power = Low | - | 5 | - | | |
| | I_{OUT} | $V_{DDA} = 1.71 \text{ V}$, 500 mV from rail | | | | | |
| SID278 | $I_{OUT_MAX_HI}$ | Power = High | 4 | - | - | mA | Output is 0.5 V to $V_{DDA} - 0.5 \text{ V}$ |
| SID279 | $I_{OUT_MAX_MID}$ | Power = Medium | 4 | - | - | | |
| SID280 | $I_{OUT_MAX_LO}$ | Power = Low | - | 2 | - | | |
| | I_{DD_Int} | Opamp block current, internal load | | | | | |
| SID269_I | $I_{DD_HI_Int}$ | Power = High | - | 1500 | 1700 | μA | - |
| SID270_I | $I_{DD_MED_Int}$ | Power = Medium | - | 700 | 900 | | - |

(table continues...)

5 Electrical specifications

Table 10 (continued) CTBm Opamp specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|-------------------------|--|------------|------------|------------------------|-------------|---|
| SID271_I | I _{DD_LOW_Int} | Power = Low | - | - | - | | - |
| | G _{BW} | V _{DDA} = 2.7 V | - | - | - | | - |
| SID272_I | G _{BW_HI_Int} | Power = High | 8 | - | - | MHz | Output is 0.25 V to V _{DDA} - 0.25 V |
| | | General opamp specs for both internal and external modes | | | | | |
| SID281 | V _{IN} | Charge-pump on, V _{DDA} = 2.7 V | -0.05 | - | V _{DDA} - 0.2 | V | - |
| SID282 | V _{CM} | Charge-pump on, V _{DDA} = 2.7 V | -0.05 | - | V _{DDA} - 0.2 | | - |
| | V _{OUT} | V _{DDA} = 2.7 V | | | | | |
| SID283 | V _{OUT_1} | Power = High, Iload = 10 mA | 0.5 | - | V _{DDA} - 0.5 | V | - |
| SID284 | V _{OUT_2} | Power = High, Iload = 1 mA | 0.2 | - | V _{DDA} - 0.2 | | - |
| SID285 | V _{OUT_3} | Power = Medium, Iload = 1 mA | 0.2 | - | V _{DDA} - 0.2 | | - |
| SID286 | V _{OUT_4} | Power = Low, Iload = 0.1 mA | 0.2 | - | V _{DDA} - 0.2 | | - |
| SID288 | V _{OS_TR} | Offset voltage, trimmed | -1.0 | ±0.5 | 1.0 | mV | High mode, input 0 V to V _{DDA} - 0.2 V |
| SID288A | V _{OS_TR} | Offset voltage, trimmed | - | ±1 | - | | Medium mode, input 0 V to V _{DDA} - 0.2 V |
| SID288B | V _{OS_TR} | Offset voltage, trimmed | - | ±2 | - | | Low mode, input 0 V to V _{DDA} - 0.2 V |
| SID290 | V _{OS_DR_TR} | Offset voltage drift, trimmed | -10 | ±3 | 10 | µV/°C | High mode |
| SID290A | V _{OS_DR_TR} | Offset voltage drift, trimmed | - | ±10 | - | | Medium mode |
| SID290B | V _{OS_DR_TR} | Offset voltage drift, trimmed | - | ±10 | - | | Low mode |
| SID291 | CMRR | DC | 70 | 80 | - | dB | Input is 0 V to V _{DDA} - 0.2 V, Output is 0.2 V to V _{DDA} - 0.2 V |

(table continues...)

5 Electrical specifications

Table 10 (continued) CTBm Opamp specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|-----------------------|---|------------|------------|------------|-------------|---|
| SID292 | PSRR | At 1 kHz, 10-mV ripple | 70 | 85 | – | | V _{DDD} = 3.6 V, high-power mode, input is 0.2 V to V _{DDA} – 0.2 V |
| | Noise | | | | | | |
| SID294 | VN2 | Input-referred, 1 kHz, Power = High | – | 72 | – | nV/rtHz | Input and output are at 0.2 V to V _{DDA} – 0.2 V |
| SID295 | VN3 | Input-referred, 10 kHz, Power = High | – | 28 | – | | |
| SID296 | VN4 | Input-referred, 100 kHz, Power = High | – | 15 | – | | |
| SID297 | C _{LOAD} | Stable up to max. load. Performance specs at 50 pF. | – | – | 125 | pF | – |
| SID298 | SLEW_RATE | Cload = 50 pF, Power = High, V _{DDA} = 2.7 V | 6 | – | – | V/μs | – |
| SID299 | T_OP_WAKE | From disable to enable, no external RC dominating | – | – | 25 | μs | – |
| SID299A | OL_GAIN | Open Loop Gain | – | 90 | – | dB | – |
| | COMP_MODE | Comparator mode; 50 mV drive, T _{rise} = T _{fall} (approx.) | | | | | |
| SID300 | TPD1 | Response time; Power = High | – | 150 | – | ns | Input is 0.2 V to V _{DDA} – 0.2 V |
| SID301 | TPD2 | Response time; Power = Medium | – | 500 | – | | |
| SID302 | TPD3 | Response time; Power = Low | – | 2500 | – | | |
| SID303 | VHYST_OP | Hysteresis | – | 10 | – | mV | – |
| SID304 | WUP_CTB | Wake-up time from Enabled to Usable | – | – | 25 | μs | – |
| | Deep Sleep Mode | Mode 2 is lowest current range. Mode 1 has higher GBW | | | | | |
| SID_DS_1 | I _{DD_HI_M1} | Mode 1, high current | – | 1400 | – | μA | 25°C |

(table continues...)

Table 10 (continued) CTBm Opamp specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|--------------------|---------------------------|------------|------------|------------|-------------|---|
| SID_DS_2 | $I_{DD_MED_M1}$ | Mode 1, medium current | – | 700 | – | MHz | 20-pF load, no DC load 0.2 V to $V_{DDA} - 0.2$ V |
| SID_DS_3 | $I_{DD_LOW_M1}$ | Mode 1, low current | – | 200 | – | | |
| SID_DS_4 | $I_{DD_HI_M2}$ | Mode 2, high current | – | 120 | – | | |
| SID_DS_5 | $I_{DD_MED_M2}$ | Mode 2, medium current | – | 60 | – | | |
| SID_DS_6 | $I_{DD_LOW_M2}$ | Mode 2, low current | – | 15 | – | | |
| SID_DS_7 | $G_{BW_HI_M1}$ | Mode 1, high current | – | 4 | – | | |
| SID_DS_8 | $G_{BW_MED_M1}$ | Mode 1, medium current | – | 2 | – | | |
| SID_DS_9 | $G_{BW_LOW_M1}$ | Mode 1, low current | – | 0.5 | – | | |
| SID_DS_10 | $G_{BW_HI_M2}$ | Mode 2, high current | – | 0.5 | – | | |
| SID_DS_11 | $G_{BW_MED_M2}$ | Mode 2, medium current | – | 0.2 | – | | |
| SID_DS_12 | $G_{BW_Low_M2}$ | Mode 2, low current | – | 0.1 | – | | |
| SID_DS_13 | $V_{OS_HI_M1}$ | Mode 1, high current | – | 5 | – | mV | With trim 25°C, 0.2 V to $V_{DDA} - 0.2$ V |
| SID_DS_14 | $V_{OS_MED_M1}$ | Mode 1, medium current | – | 5 | – | | |
| SID_DS_15 | $V_{OS_LOW_M1}$ | Mode 1, low current | – | 5 | – | | |
| SID_DS_16 | $V_{OS_HI_M2}$ | Mode 2, high current | – | 5 | – | | |
| SID_DS_17 | $V_{OS_MED_M2}$ | Mode 2, medium current | – | 5 | – | | |
| SID_DS_18 | $V_{OS_LOW_M2}$ | Mode 2, low current | – | 5 | – | | |
| SID_DS_19 | $I_{OUT_HI_M1}$ | Mode 1, high current | – | 10 | – | mA | Output is 0.5 V to $V_{DDA} - 0.5$ V |
| SID_DS_20 | $I_{OUT_MED_M1}$ | Mode 1, medium current | – | 10 | – | | |
| SID_DS_21 | $I_{OUT_LOW_M1}$ | Mode 1, low current | – | 4 | – | | |
| SID_DS_22 | $I_{OUT_HI_M2}$ | Mode 2, high current | – | 1 | – | | |
| SID_DS_23 | $I_{OUT_MED_M2}$ | Mode 2, medium current | – | 1 | – | – | – |
| SID_DS_24 | $I_{OUT_LOW_M2}$ | Mode 2, low current | – | 0.5 | – | | |

5 Electrical specifications

5.3.2 Comparator

Table 11 Comparator DC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|---------------|---|-----|-----|------------------|------------------|--|
| SID84 | $V_{OFFSET1}$ | Input offset voltage, factory trim | – | – | ± 10 | mV | – |
| SID85 | $V_{OFFSET2}$ | Input offset voltage, custom trim | – | – | ± 4 | | – |
| SID86 | V_{HYST} | Hysteresis when enabled | – | 10 | 35 | | – |
| SID87 | V_{ICM1} | Input common mode voltage in normal mode | 0 | – | $V_{DDD} - 0.1$ | V | Modes 1 and 2 |
| SID247 | V_{ICM2} | Input common mode voltage in low power mode | 0 | – | V_{DDD} | | – |
| SID247A | V_{ICM3} | Input common mode voltage in ultra low power mode | 0 | – | $V_{DDD} - 1.15$ | | $V_{DDD} \geq 2.2 \text{ V at } -40^\circ\text{C}$ |
| SID88 | C_{MRR} | Common mode rejection ratio | 50 | – | – | dB | $V_{DDD} \geq 2.7 \text{ V}$ |
| SID88A | C_{MRR} | Common mode rejection ratio | 42 | – | – | | |
| SID89 | I_{CMP1} | Block current, normal mode | – | – | 400 | μA | – |
| SID248 | I_{CMP2} | Block current, low power mode | – | – | 100 | | – |
| SID259 | I_{CMP3} | Block current in ultra low-power mode | – | – | 6 | | $V_{DDD} \geq 2.2 \text{ V at } -40^\circ\text{C}$ |
| SID90 | Z_{CMP} | DC Input impedance of comparator | 35 | – | – | $\text{M}\Omega$ | – |

Table 12 Comparator AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|---|-----|-----|-----|---------------|--|
| SID91 | TRESP1 | Response time, normal mode, 50 mV overdrive | – | 38 | 110 | ns | – |
| SID258 | TRESP2 | Response time, low power mode, 50 mV overdrive | – | 70 | 200 | | – |
| SID92 | TRESP3 | Response time, ultra-low power mode, 200 mV overdrive | – | 2.3 | 15 | μs | $V_{DDD} \geq 2.2 \text{ V at } -40^\circ\text{C}$ |

5.3.3 Temperature sensor

Table 13 Temperature sensor specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|-----------------------------|-----|---------|-----|------|--------------------|
| SID93 | TSENSACC | Temperature sensor accuracy | -5 | ± 1 | 5 | °C | -40°C to +85°C |

5.3.4 SAR

Table 14 SAR specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------------------|-----------|------------------------------------|-----------------|-----|------------------|------|---------------------------------|
| SAR ADC DC specifications | | | | | | | |
| SID94 | A_RES | Resolution | – | – | 12 | bits | – |
| SID95 | A_CHNLS_S | Number of channels - single ended | – | – | 16 | | – |
| SID96 | A_CHNKS_D | Number of channels - differential | – | – | 4 | | Diff inputs use neighboring I/O |
| SID97 | A-MONO | Monotonicity | – | – | – | | Yes |
| SID98 | A_GAINERR | Gain error | – | – | ±0.1 | % | With external reference. |
| SID99 | A_OFFSET | Input offset voltage | – | – | 2 | mV | Measured with 1-V reference |
| SID100 | A_ISAR | Current consumption | – | – | 1 | mA | – |
| SID101 | A_VINS | Input voltage range - single ended | V _{SS} | – | V _{DDA} | V | – |
| SID102 | A_VIND | Input voltage range - differential | V _{SS} | – | V _{DDA} | | – |
| SID103 | A_INRES | Input resistance | – | – | 2.2 | kΩ | – |
| SID104 | A_INCAP | Input capacitance | – | – | 10 | pF | – |
| SID260 | VREFSAR | Trimmed internal reference to SAR | 1.188 | 1.2 | 1.212 | V | – |

SAR ADC AC specifications

| | | | | | | | |
|---------|--------|--|------|---|----------|------|--|
| SID106 | A_PSRR | Power supply rejection ratio | 70 | – | – | dB | – |
| SID107 | A_CMRR | Common mode rejection ratio | 66 | – | – | | Measured at 1 V |
| SID108 | A_SAMP | Sample rate | – | – | 1 | Msps | – |
| SID109 | A_SNR | Signal-to-noise and distortion ratio (SINAD) | 65 | – | – | dB | F _{IN} = 10 kHz |
| SID110 | A_BW | Input bandwidth without aliasing | – | – | A_samp/2 | kHz | – |
| SID111 | A_INL | Integral non linearity. V _{DD} = 1.71 V to 5.5 V, 1 Msps | -1.7 | – | 2 | LSB | V _{REF} = 1 V to V _{DD} |
| SID111A | A_INL | Integral non linearity. V _{DD} = 1.71 V to 3.6 V, 1 Msps | -1.5 | – | 1.7 | | V _{REF} = 1.71 V to V _{DD} |
| SID111B | A_INL | Integral non linearity. V _{DD} = 1.71 V to 5.5 V, 500 ksps | -1.5 | – | 1.7 | | V _{REF} = 1 V to V _{DD} |

(table continues...)

5 Electrical specifications

Table 14 (continued) SAR specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions | |
|---------|------------|--|-----|-----|-----|------|-------------------------------------|-------------------|
| SID112 | A_DNL | Differential non linearity. $V_{DD} = 1.71\text{ V to }5.5\text{ V}, 1\text{ Msps}$ | -1 | - | 2.2 | | $V_{REF} = 1\text{ V to }V_{DD}$ | |
| SID112A | A_DNL | Differential non linearity. $V_{DD} = 1.71\text{ V to }3.6\text{ V}, 1\text{ Msps}$ | -1 | - | 2 | | $V_{REF} = 1.71\text{ V to }V_{DD}$ | |
| SID112B | A_DNL | Differential non linearity. $V_{DD} = 1.71\text{ V to }5.5\text{ V}, 500\text{ ksps}$ | -1 | - | 2.2 | | $V_{REF} = 1\text{ V to }V_{DD}$ | |
| SID113 | A_THD | Total harmonic distortion | - | - | -65 | dB | $f_{in} = 10\text{ kHz}$ | |
| SID261 | FSARINTREF | SAR operating speed without external reference bypass | | - | - | 100 | ksps | 12-bit resolution |

5.3.5 CSD and IDAC

Table 15 CSD and IDAC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|-------------|----------------|---|-----|-----|-----------------|---------------|---|
| SYS.PER#3 | VDD_RIPPLE | Max allowed ripple on power supply, DC to 10 MHz | - | - | ± 50 | mV | $V_{DD} > 2\text{ V (with ripple), }25^\circ\text{C }T_A,$ Sensitivity = 0.1 pF |
| SYS.PER#16 | VDD_RIPPLE_1.8 | Max allowed ripple on power supply, DC to 10 MHz | - | - | ± 25 | | $V_{DD} > 1.75\text{ V (with ripple), }25^\circ\text{C }T_A,$ Parasitic capacitance (C_P) < 20 pF, Sensitivity $\geq 0.4\text{ pF}$ |
| SID.CSD.BLK | ICSD | Maximum block current | - | - | 4000 | μA | Maximum block current for both IDACs in dynamic (switching) mode including comparators, buffer, and reference generator. |
| SID.CSD#15 | V_{REF} | Voltage reference for CSD and comparator | 0.6 | 1.2 | $V_{DDA} - 0.6$ | V | $V_{DDA} - 0.6\text{ or }4.4,\text{ whichever is lower}$ |
| SID.CSD#15A | VREF_EXT | External voltage reference for CSD and comparator | 0.6 | - | $V_{DDA} - 0.6$ | | $V_{DDA} - 0.6\text{ or }4.4,\text{ whichever is lower}$ |
| SID.CSD#16 | IDAC1IDD | IDAC1 (7-bits) block current | - | - | 1750 | μA | - |
| SID.CSD#17 | IDAC2IDD | IDAC2 (7-bits) block current | - | - | 1750 | | - |

(table continues...)

5 Electrical specifications

Table 15 (continued) CSD and IDAC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|------------|--|------|-----|-----------------|-------|---|
| SID308 | VCSD | Voltage range of operation | 1.71 | – | 5.5 | V | 1.8 V ± 5% or 1.8 V to 5.5 V |
| SID308A | VCOMPIDAC | Voltage compliance range of IDAC | 0.6 | – | $V_{DDA} - 0.6$ | | $V_{DDA} - 0.6$ or 4.4, whichever is lower |
| SID309 | IDAC1DNL | DNL | -1 | – | 1 | LSB | – |
| SID310 | IDAC1INL | INL | -2 | – | 2 | | INL is ±5.5 LSB for $V_{DDA} < 2$ V |
| SID311 | IDAC2DNL | DNL | -1 | – | 1 | | – |
| SID312 | IDAC2INL | INL | -2 | – | 2 | | INL is ±5.5 LSB for $V_{DDA} < 2$ V |
| SID313 | SNR | Ratio of counts of finger to noise. Guaranteed by characterization | 5 | – | – | Ratio | Capacitance range of 5 to 35 pF, 0.1-pF sensitivity. All use cases. $V_{DDA} > 2$ V. |
| SID314 | IDAC1CRT1 | Output current of IDAC1 (7 bits) in low range | 4.2 | – | 5.4 | µA | LSB = 37.5-nA typ. |
| SID314A | IDAC1CRT2 | Output current of IDAC1 (7 bits) in medium range | 34 | – | 41 | | LSB = 300-nA typ. |
| SID314B | IDAC1CRT3 | Output current of IDAC1 (7 bits) in high range | 275 | – | 330 | | LSB = 2.4-µA typ. |
| SID314C | IDAC1CRT12 | Output current of IDAC1 (7 bits) in low range, 2X mode | 8 | – | 10.5 | | LSB = 75-nA typ. |
| SID314D | IDAC1CRT22 | Output current of IDAC1 (7 bits) in medium range, 2X mode | 69 | – | 82 | | LSB = 600-nA typ. |
| SID314E | IDAC1CRT32 | Output current of IDAC1 (7 bits) in high range, 2X mode | 540 | – | 660 | | LSB = 4.8-µA typ. |
| SID315 | IDAC2CRT1 | Output current of IDAC2 (7 bits) in low range | 4.2 | – | 5.4 | | LSB = 37.5-nA typ. |
| SID315A | IDAC2CRT2 | Output current of IDAC2 (7 bits) in medium range | 34 | – | 41 | | LSB = 300-nA typ. |
| SID315B | IDAC2CRT3 | Output current of IDAC2 (7 bits) in high range | 275 | – | 330 | | LSB = 2.4-µA typ. |
| SID315C | IDAC2CRT12 | Output current of IDAC2 (7 bits) in low range, 2X mode | 8 | – | 10.5 | | LSB = 75-nA typ. |

(table continues...)

5 Electrical specifications

Table 15 (continued) CSD and IDAC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|---------------|---|-----|-----|----------|---------|---|
| SID315D | IDAC2CRT22 | Output current of IDAC2 (7 bits) in medium range, 2X mode | 69 | – | 82 | | LSB = 600-nA typ. |
| SID315E | IDAC2CRT32 | Output current of IDAC2 (7 bits) in high range, 2X mode | 540 | – | 660 | | LSB = 4.8- μ A typ. |
| SID315F | IDAC3CRT13 | Output current of IDAC in 8-bit mode in low range | 8 | – | 10.5 | | LSB = 37.5-nA typ. |
| SID315G | IDAC3CRT23 | Output current of IDAC in 8-bit mode in medium range | 69 | – | 82 | | LSB = 300-nA typ. |
| SID315H | IDAC3CRT33 | Output current of IDAC in 8-bit mode in high range | 540 | – | 660 | μ A | LSB = 2.4- μ A typ. |
| SID320 | IDACOFFSET | All zeroes input | – | – | 1 | LSB | Polarity set by Source or Sink. Offset is 2 LSBs for 37.5 nA/LSB mode |
| SID321 | IDACGAIN | Full-scale error less offset | – | – | \pm 10 | % | – |
| SID322 | IDACMISMATCH1 | Mismatch between IDAC1 and IDAC2 in Low mode | – | – | 9.2 | LSB | LSB = 37.5-nA typ. |
| SID322A | IDACMISMATCH2 | Mismatch between IDAC1 and IDAC2 in Medium mode | – | – | 5.6 | | LSB = 300-nA typ. |
| SID322B | IDACMISMATCH3 | Mismatch between IDAC1 and IDAC2 in High mode | – | – | 6.8 | | LSB = 2.4- μ A typ. |
| SID323 | IDACSET8 | Settling time to 0.5 LSB for 8-bit IDAC | – | – | 10 | μ s | Full-scale transition. No external load. |
| SID324 | IDACSET7 | Settling time to 0.5 LSB for 7-bit IDAC | – | – | 10 | | Full-scale transition. No external load. |
| SID325 | CMOD | External modulator capacitor. | – | 2.2 | – | nF | 5-V rating, X7R or NP0 cap. |

5.3.6 10-bit CapSense ADC

Table 16 10-bit CAPSENSE™ ADC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------|-----------|---|-----------|-----|-----------|------------|--|
| SIDA94 | A_RES | Resolution | – | – | 10 | bits | Auto-zeroing is required every millisecond |
| SIDA95 | A_CHNLS_S | Number of channels - single ended | – | – | 16 | | Defined by AMUX Bus |
| SIDA97 | A-MONO | Monotonicity | – | – | – | Yes | – |
| SIDA98 | A_GAINERR | Gain error | – | – | ±2 | % | In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF |
| SIDA99 | A_OFFSET | Input offset voltage | – | – | 3 | mV | In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF |
| SIDA100 | A_ISAR | Current consumption | – | – | 0.25 | mA | – |
| SIDA101 | A_VINS | Input voltage range - single ended | V_{SSA} | – | V_{DDA} | V | – |
| SIDA103 | A_INRES | Input resistance | – | 2.2 | – | K Ω | – |
| SIDA104 | A_INCAP | Input capacitance | – | 20 | – | pF | – |
| SIDA106 | A_PSRR | Power supply rejection ratio | – | 60 | – | dB | In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF |
| SIDA107 | A_TACQ | Sample acquisition time | – | 1 | – | μs | – |
| SIDA108 | A_CONV8 | Conversion time for 8-bit resolution at conversion rate = $F_{hclk}/(2^{(N+2)})$. Clock frequency = 48 MHz. | – | – | 21.3 | | Does not include acquisition time. Equivalent to 44.8 ksps including acquisition time. |
| SIDA108A | A_CONV10 | Conversion time for 10-bit resolution at conversion rate = $F_{hclk}/(2^{(N+2)})$. Clock frequency = 48 MHz. | – | – | 85.3 | | Does not include acquisition time. Equivalent to 11.6 ksps including acquisition time. |
| SIDA109 | A SND | Signal-to-noise and Distortion ratio (SINAD) | – | 61 | – | dB | With 10-Hz input sine wave, external 2.4-V reference, V_{REF} (2.4 V) mode |
| SIDA110 | A_BW | Input bandwidth without aliasing | – | – | 22.4 | KHz | 8-bit resolution |
| SIDA111 | A_INL | Integral Non Linearity. 1 ksps | – | – | 2 | LSB | $V_{REF} = 2.4$ V or greater |

(table continues...)

Table 16 (continued) 10-bit CAPSENSE™ ADC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|---------------------------------------|-----|-----|-----|------|--------------------|
| SIDA112 | A_DNL | Differential Non Linearity. 1 ksps | - | - | 1 | | - |

5.4 Digital peripherals

5.4.1 Timer Counter Pulse-width Modulator (TCPWM)

Table 17 TCPWM specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|--------------|-----------------------|-------------------------------------|------------------|-----|----------------|------|--|
| SID.TCPWM.1 | ITCPWM1 | Block current consumption at 3 MHz | - | - | 45 | µA | All modes (TCPWM) |
| SID.TCPWM.2 | ITCPWM2 | Block current consumption at 12 MHz | - | - | 155 | | |
| SID.TCPWM.2A | ITCPWM3 | Block current consumption at 48 MHz | - | - | 650 | | |
| SID.TCPWM.3 | TCPWM _{FREQ} | Operating frequency | - | - | F _c | MHz | F _c max = CLK_SYS Maximum = 48 MHz |
| SID.TCPWM.4 | TPWM _{ENEXT} | Input trigger pulse width | 2/F _c | - | - | ns | For all trigger events ¹⁾ |
| SID.TCPWM.5 | TPWM _{EXT} | Output trigger pulse widths | 2/F _c | - | - | | Minimum possible width of Overflow, Underflow, and CC (Counter equals Compare value) outputs |
| SID.TCPWM.5A | TC _{RES} | Resolution of counter | 1/F _c | - | - | | Minimum time between successive counts |
| SID.TCPWM.5B | PWM _{RES} | PWM resolution | 1/F _c | - | - | | Minimum pulse width of PWM Output |
| SID.TCPWM.5C | Q _{RES} | Quadrature inputs resolution | 1/F _c | - | - | | Minimum pulse width between Quadrature phase inputs |

1) Trigger events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.

5.4.2 I²C

Table 18 Fixed I²C DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-------------------|--------------------------------------|-----|-----|-----|------|--------------------|
| SID149 | I _{I2C1} | Block current consumption at 100 kHz | - | - | 50 | µA | - |

(table continues...)

5 Electrical specifications

Table 18 (continued) Fixed I²C DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|------------------------------|---|-----|-----|-----|------|--------------------|
| SID150 | I _{I²C2} | Block current consumption at 400 kHz | - | - | 135 | - | - |
| SID151 | I _{I²C3} | Block current consumption at 1 Mbps | - | - | 310 | | - |
| SID152 | I _{I²C4} | I ² C enabled in Deep Sleep mode | - | - | 1.4 | | - |

1) Guaranteed by characterization.

Table 19 Fixed I²C AC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|------------------------------|-------------|-----|-----|-----|------|--------------------|
| SID153 | F _{I²C1} | Bit rate | - | - | 1 | Msps | - |

1) Guaranteed by characterization.

5.4.3 SPI

Table 20 SPI DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|-------------------------------------|-----|-----|-----|------|--------------------|
| SID163 | ISPI1 | Block current consumption at 1 Mbps | - | - | 360 | µA | - |
| SID164 | ISPI2 | Block current consumption at 4 Mbps | - | - | 560 | | - |
| SID165 | ISPI3 | Block current consumption at 8 Mbps | - | - | 600 | | - |

1) Guaranteed by characterization.

Table 21 SPI AC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|---|-----|-----|-----|------|--------------------|
| SID166 | FSPI | SPI operating frequency (Master; 6X oversampling) | - | - | 8 | MHz | SID166 |

Fixed SPI Master Mode AC specifications

| | | | | | | | |
|--------|------|---|----|---|----|----|----------------------------------|
| SID167 | TDMO | MOSI valid after SClock driving edge | - | - | 15 | ns | - |
| SID168 | TDSI | MISO valid before SClock capturing edge | 20 | - | - | | Full clock, late MISO sampling |
| SID169 | THMO | Previous MOSI data hold time | 0 | - | - | | Referred to Slave capturing edge |

Fixed SPI Slave Mode AC specifications

(table continues...)

5 Electrical specifications

Table 21 (continued) SPI AC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------|---|-----|-----|-----------------|-----------------------|--------------------|
| SID170 | TDMI | MOSI valid before Sclock capturing edge | 40 | – | – | ns | – |
| SID171 | TDSO | MISO valid after Sclock driving edge | – | – | 42 + (3 × Tcpu) | $T_{CPU} = 1/F_{CPU}$ | – |
| SID171A | TDSO_EXT | MISO valid after Sclock driving edge in External Clock mode | – | – | 48 | | |
| SID172 | THSO | Previous MISO data hold time | 0 | – | – | | |
| SID172A | TSSELSSCK | SSEL valid to first SCK valid edge | 100 | – | – | | |

1) Guaranteed by characterization.

5.4.4 UART

Table 22 UART DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|--------------------|--|-----|-----|-----|------|--------------------|
| SID160 | I _{UART1} | Block current consumption at 100 Kbps | – | – | 55 | µA | – |
| SID161 | I _{UART2} | Block current consumption at 1000 Kbps | – | – | 312 | – | – |

1) Guaranteed by characterization.

Table 23 UART AC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-------------------|-------------|-----|-----|-----|------|--------------------|
| SID162 | F _{UART} | Bit rate | – | – | 1 | Mbps | – |

1) Guaranteed by characterization.

5.4.5 LCD

Table 24 LCD direct drive DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------------------|---|-----|-----|------|------|-------------------------------------|
| SID154 | I _{LCDLOW} | Operating current in low power mode | – | 5 | – | µA | 16 × 4 small segment disp. at 50 Hz |
| SID155 | C _{LCDCAP} | LCD capacitance per segment/common driver | – | 500 | 5000 | pF | – |
| SID156 | LCD _{OFFSET} | Long-term segment offset | – | 20 | – | mV | – |

(table continues...)

5 Electrical specifications

Table 24 (continued) LCD direct drive DC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|---------------------|---|-----|-----|-----|------|---------------------------------|
| SID157 | I _{LCDOP1} | LCD system operating current V _{bias} = 5 V | - | 2 | - | mA | 32 × 4 segments. 50 Hz. 25°C |
| SID158 | I _{LCDOP2} | LCD system operating current V _{bias} = 3.3 V | - | 2 | - | | 32 × 4 segments. 50 Hz. 25°C |

1) Guaranteed by characterization.

Table 25 LCD direct drive AC specifications¹⁾

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|------------------|----------------|-----|-----|-----|------|--------------------|
| SID159 | F _{LCD} | LCD frame rate | 10 | 50 | 150 | Hz | - |

1) Guaranteed by characterization.

5.5 Memory

5.5.1 Flash

Table 26 Flash DC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-----------------|---------------------------|------|-----|-----|------|--------------------|
| SID173 | V _{PE} | Erase and program voltage | 1.71 | - | 5.5 | V | - |

Table 27 Flash AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|---------------------------------------|--|-------|-----|-----|---------|-------------------------|
| SID174 | T _{ROWWRITE} ¹⁾ | Row (block) write time (erase and program) | - | - | 20 | ms | Row (block) = 128 bytes |
| SID175 | T _{ROWERASE} ¹⁾ | Row erase time | - | - | 16 | | - |
| SID176 | T _{ROWPROGRAM} ¹⁾ | Row program time after erase | - | - | 4 | | - |
| SID178 | T _{BULKERASE} ¹⁾ | Bulk erase time (64 KB) | - | - | 35 | | - |
| SID180 ²⁾ | T _{DEVPROG} ¹⁾ | Total device program time | - | - | 7 | Seconds | - |
| SID181 ²⁾ | F _{END} | Flash endurance | 100 K | - | - | Cycles | - |
| SID182 ²⁾ | F _{RET} | Flash retention. T _A ≤ 55 °C, 100 K P/E cycles | 20 | - | - | Years | - |

(table continues...)

5 Electrical specifications

Table 27 (continued) Flash AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|-----------------------|-----------|---|-----|-----|-----|-------|--------------------------|
| SID182A ²⁾ | - | Flash retention. $T_A \leq 85^\circ\text{C}$, 10 K P/E cycles | 10 | - | - | | - |
| SID182B | - | Flash retention. $T_A \leq 105^\circ\text{C}$, 10K P/E cycles, \leq three years at $T_A \geq 85^\circ\text{C}$ | 10 | - | 20 | Years | - |
| SID256 | TWS48 | Number of Wait states at 48 MHz | 2 | - | - | | CPU execution from flash |
| SID257 | TWS24 | Number of Wait states at 24 MHz | 1 | - | - | | |

1) It can take as much as 20 milliseconds to write to flash. During this time the device should not be Reset, or Flash operations may be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watchdogs. Make certain that these are not inadvertently activated.

2) Guaranteed by characterization.

5.6 System resources

5.6.1 Power-on reset (POR)

Table 28 Power-on reset (POR)

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|----------------|------------------------|------|-----|-----|------|----------------------------|
| SID.CLK#6 | SR_POWER_UP | Power supply slew rate | 1 | - | 67 | V/ms | At power-up and power-down |
| SID185 ¹⁾ | $V_{RISEIPOR}$ | Rising trip voltage | 0.80 | - | 1.5 | V | - |
| SID186 ¹⁾ | $V_{FALLIPOR}$ | Falling trip voltage | 0.70 | - | 1.4 | | - |

1) Guaranteed by characterization.

Table 29 Brown-out detect (BOD) for V_{CCD}

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|-----------------|--|------|-----|------|------|--------------------|
| SID190 ¹⁾ | $V_{FALLPPOR}$ | BOD trip voltage in Active and Sleep modes | 1.48 | - | 1.62 | V | - |
| SID192 ¹⁾ | $V_{FALLDPSLP}$ | BOD trip voltage in Deep Sleep | 1.11 | - | 1.5 | | - |

1) Guaranteed by characterization

5 Electrical specifications

5.6.2 SWD interface

Table 30 SWD interface specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|-----------------------|--------------|---|-----------------|-----|----------------|------|---------------------------------------|
| SID213 | F_SWDCLK1 | $3.3 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$ | - | - | 14 | MHz | SWDCLK $\leq 1/3$ CPU clock frequency |
| SID214 | F_SWDCLK2 | $1.71 \text{ V} \leq V_{DD} \leq 3.3 \text{ V}$ | - | - | 7 | | SWDCLK $\leq 1/3$ CPU clock frequency |
| SID215 ¹⁾ | T_SWDI_SETUP | $T = 1/f \text{ SWDCLK}$ | $0.25 \times T$ | - | - | ns | - |
| SID216 ¹⁾ | T_SWDI_HOLD | $T = 1/f \text{ SWDCLK}$ | $0.25 \times T$ | - | - | | - |
| SID217 ¹⁾ | T_SWDO_VALID | $T = 1/f \text{ SWDCLK}$ | - | - | $0.5 \times T$ | | - |
| SID217A ¹⁾ | T_SWDO_HOLD | $T = 1/f \text{ SWDCLK}$ | 1 | - | - | | - |
| | | | | | | | |

1) Guaranteed by characterization.

5.6.3 IMO

Table 31 IMO DC specifications

(Guaranteed by design)

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------|-------------------|---------------------------------|-----|-----|-----|------|--------------------|
| SID218 | I _{IMO1} | IMO operating current at 48 MHz | - | - | 250 | µA | - |
| SID219 | I _{IMO2} | IMO operating current at 24 MHz | - | - | 180 | µA | |

Table 32 IMO AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|---------------------------|----------------------|---|-----|-----|------|------|---|
| SID223 ²⁾ | F _{IMOTOL1} | Frequency variation at 24, 32, and 48 MHz (trimmed) | - | - | ±2.0 | % | At -40°C to 85°C, for industrial temperature range and original extended industrial range parts |
| SID223A ^{1), 2)} | | | - | - | ±2.5 | % | At -40°C to 105°C, for all extended industrial temperature range parts |
| SID223B ^{1), 2)} | | | - | - | ±2.0 | % | At -30°C to 105°C, for enhanced IMO extended industrial temperature range parts |

(table continues...)

5 Electrical specifications

Table 32 (continued) IMO AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|--------------------------|-------------------------|----------------------|------------|------------|------------|-------------|---|
| SID223C ^{1) 2)} | | | – | – | ±1.5 | % | At –20°C to 105°C, for enhanced IMO extended industrial temperature range parts |
| SID223D ^{1) 2)} | | | – | – | ±1.25 | % | At 0°C to 85°C, for enhanced IMO extended industrial temperature range parts |
| SID226 | T _{STARTIMO} | IMO startup time | – | – | 7 | μs | – |
| SID228 | T _{JITRMSIMO2} | RMS jitter at 24 MHz | – | 145 | – | ps | – |

1) The enhanced IMO extended temperature range parts replace the original extended industrial temperature range parts. For details on how to identify enhanced IMO extended temperature range parts, please refer to [KBA235887](#).

2) Evaluated by characterization. Does not take into account soldering or board-level effects.

5.6.4 ILO

Table 33 ILO DC specifications

(Guaranteed by design)

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|-------------------|-----------------------|------------|------------|------------|-------------|---------------------------|
| SID231 ¹⁾ | I _{ILO1} | ILO operating current | – | 0.3 | 1.05 | μA | – |

1) Guaranteed by characterization.

Table 34 ILO AC specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|------------------------|---------------------|------------|------------|------------|-------------|---------------------------|
| SID234 ¹⁾ | T _{STARTILO1} | ILO startup time | – | – | 2 | ms | – |
| SID236 ¹⁾ | T _{ILODUTY} | ILO duty cycle | 40 | 50 | 60 | % | – |
| SID237 | F _{ILOTRIM1} | ILO frequency range | 20 | 40 | 80 | kHz | – |

1) Guaranteed by characterization.

5.6.5 WCO

Table 35 WCO specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|------------------|------------------------------|------------|------------|------------|-------------|---------------------------|
| SID398 | FWCO | Crystal frequency | – | 32.768 | – | kHz | – |
| SID399 | FTOL | Frequency tolerance | – | 50 | 250 | ppm | With 20-ppm crystal |
| SID400 | ESR | Equivalent series resistance | – | 50 | – | kΩ | – |
| SID401 | PD | Drive level | – | – | 1 | μW | – |

(table continues...)

Table 35 (continued) WCO specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|------------------|-------------------------------------|------------|------------|------------|-------------|---------------------------|
| SID402 | TSTART | Startup time | - | - | 500 | ms | - |
| SID403 | CL | Crystal load capacitance | 6 | - | 12.5 | pF | - |
| SID404 | C0 | Crystal shunt capacitance | - | 1.35 | - | | - |
| SID405 | IWCO1 | Operating current (high power mode) | - | - | 8 | mA | - |
| SID406 | IWCO2 | Operating current (low power mode) | - | - | 1 | | - |

5.6.6 External clock

Table 36 External clock specifications

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|------------------|--|------------|------------|------------|-------------|---------------------------|
| SID305 ¹⁾ | ExtClkFreq | External clock input frequency | 0 | - | 48 | MHz | - |
| SID306 ¹⁾ | ExtClkDuty | Duty cycle; measured at V _{DD} /2 | 45 | - | 55 | % | - |

1) Guaranteed by characterization.

5.6.7 Block

Table 37 Block specs

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------------|------------------------|------------------------------------|------------|------------|------------|-------------|---------------------------|
| SID262 ¹⁾ | T _{CLKSWITCH} | System clock source switching time | 3 | - | 4 | Periods | - |

1) Guaranteed by characterization.

5.6.8 Smart I/O

Table 38 Smart I/O pass-through time (Delay in Bypass mode)

| Spec ID | Parameter | Description | Min | Typ | Max | Unit | Details/conditions |
|----------------|------------------|---|------------|------------|------------|-------------|---------------------------|
| SID252 | PRG_BYPASS | Max delay added by Smart I/O in Bypass mode | - | - | 1.6 | ns | - |

6 Ordering information

6 Ordering information

The products for the PSoC™ 4100S family are listed in the following table.

Table 39 Ordering information

| Category | Product | Features | | | | | | | | | | | | Package | | | Temperature Range (°C) | | | |
|----------|-------------------|---------------------|------------|-----------|--------------|-----|----------------|----------------|-----------------|----------------|--------------|------------|------------|---------|------------------------------|------------|------------------------|-----------|-----------|----------------|
| | | Max CPU speed (MHz) | Flash (KB) | SRAM (KB) | Opamp (CTBm) | CSD | 10-bit CSD ADC | 12-bit SAR ADC | ADC Sample rate | LP Comparators | TCPWM Blocks | SCB Blocks | Smart I/Os | GPIO | 35-ball WLCSP (0.35mm pitch) | 32-lead FN | 40L QFN | 48LD TQFP | 44LD TQFP | |
| 4124 | CY8C4124FNI-S403T | 24 | 16 | 4 | 2 | 0 | 1 | 0 | | 2 | 5 | 2 | 8 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4124FNI-S413T | 24 | 16 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4124LQI-S412T | 24 | 16 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4124LQI-S413T | 24 | 16 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4124AZI-S413T | 24 | 16 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| | CY8C4124FNI-S433T | 24 | 16 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4124FNQ-S433T | 24 | 16 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 105°C |
| | CY8C4124LQI-S432T | 24 | 16 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4124LQI-S433T | 24 | 16 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4124AZI-S433T | 24 | 16 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| 4125 | CY8C4125FNI-S423T | 24 | 32 | 4 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4125LQI-S422T | 24 | 32 | 4 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4125LQI-S423T | 24 | 32 | 4 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4125AZI-S423T | 24 | 32 | 4 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |

(table continues...)

6 Ordering information

Table 39 (continued) Ordering information

| Category | Product | Features | | | | | | | | | | | | Package | | | | Temperature Range (°C) | | |
|----------|-------------------|---------------------|------------|-----------|--------------|-----|----------------|----------------|-----------------|----------------|--------------|------------|------------|---------|------------------------------|------------|---------|------------------------|---------------|----------------|
| | | Max CPU speed (MHz) | Flash (KB) | SRAM (KB) | Opamp (CTBm) | CSD | 10-bit CSD ADC | 12-bit SAR ADC | ADC Sample rate | LP Comparators | TCPWM Blocks | SCB Blocks | Smart I/Os | GPIO | 35-ball WLCSP (0.35mm pitch) | 32-lead FN | 40L QFN | 48LD TQFP | 44LD TQFP | |
| 4126 | CY8C4125AXI-S423 | 24 | 32 | 4 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | -40°C to 85°C | |
| | CY8C4125FNI-S413T | 24 | 32 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4125LQI-S412T | 24 | 32 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4125LQI-S413T | 24 | 32 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4125AZI-S413T | 24 | 32 | 4 | 2 | 1 | 1 | 0 | | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| | CY8C4125FNI-S433T | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4125FNQ-S433T | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 31 | X | - | - | - | - | -40°C to 105°C |
| | CY8C4125LQI-S432 | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4125LQQ-S432 | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 27 | - | X | - | - | - | -40°C to 105°C |
| | CY8C4125LQI-S433 | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4125AZI-S433T | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| | CY8C4125AZQ-S433 | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 105°C |
| | CY8C4125AXI-S433 | 24 | 32 | 4 | 2 | 1 | 1 | 1 | 806 ksps | 2 | 5 | 2 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| 4126 | CY8C4126AZI-S423T | 24 | 64 | 8 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| | CY8C4126AZQ-S423 | 24 | 64 | 8 | 2 | 0 | 1 | 1 | 806 ksps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | -40°C to 105°C |

(table continues...)

6 Ordering information

Table 39 (continued) Ordering information

| Category | Product | Features | | | | | | | | | | | | Package | | | | Temperature Range (°C) | | | |
|----------|-------------------|---------------------|------------|-----------|--------------|-----|----------------|----------------|-----------------|----------------|--------------|------------|------------|---------|------------------------------|------------|---------|------------------------|-----------|----------------|----------------|
| | | Max CPU speed (MHz) | Flash (KB) | SRAM (KB) | Opamp (CTBm) | CSD | 10-bit CSD ADC | 12-bit SAR ADC | ADC Sample rate | LP Comparators | TCPWM Blocks | SCB Blocks | Smart I/Os | GPIO | 35-ball WLCSP (0.35mm pitch) | 32-lead FN | 40L QFN | 48LD TQFP | 44LD TQFP | | |
| 4145 | CY8C4126AXI-S423 | 24 | 64 | 8 | 2 | 0 | 1 | 1 | 806 ksp | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4126AZI-S433T | 24 | 64 | 8 | 2 | 1 | 1 | 1 | 806 ksp | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4126AZQ-S433 | 24 | 64 | 8 | 2 | 1 | 1 | 1 | 806 ksp | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 105°C | |
| | CY8C4126AXI-S433 | 24 | 64 | 8 | 2 | 1 | 1 | 1 | 806 ksp | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4126AXQ-S433 | 24 | 64 | 8 | 2 | 1 | 1 | 1 | 806 ksp | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 105°C | |
| 4146 | CY8C4145AZI-S423T | 48 | 32 | 4 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 2 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4145AZQ-S433 | 48 | 32 | 4 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 2 | 16 | 36 | - | - | - | - | X | -40°C to 105°C | |
| | CY8C4145AXI-S423 | 48 | 32 | 4 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 2 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4145AXI-S433 | 48 | 32 | 4 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 2 | 16 | 36 | - | - | - | - | X | -40°C to 85°C | |
| | CY8C4145AXQ-S433 | 48 | 32 | 4 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 2 | 16 | 36 | - | - | - | - | X | -40°C to 105°C | |
| 4147 | CY8C4146FNI-S423T | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 31 | X | - | - | - | - | - | -40°C to 85°C |
| | CY8C4146LQI-S422T | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 27 | - | X | - | - | - | - | -40°C to 85°C |
| | CY8C4146LQQ-S422 | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 27 | - | X | - | - | - | - | -40°C to 105°C |
| | CY8C4146LQI-S423T | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 34 | - | - | X | - | - | - | -40°C to 85°C |
| | CY8C4146AZI-S423T | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | - | -40°C to 85°C |

(table continues...)

6 Ordering information

Table 39 (continued) Ordering information

| Category | Product | Features | | | | | | | | | | | | Package | | | | Temperature Range (°C) | | |
|----------|-------------------|---------------------|------------|-----------|--------------|-----|----------------|----------------|-----------------|----------------|--------------|------------|------------|---------|------------------------------|------------|---------|------------------------|-----------|----------------|
| | | Max CPU speed (MHz) | Flash (KB) | SRAM (KB) | Opamp (CTBm) | CSD | 10-bit CSD ADC | 12-bit SAR ADC | ADC Sample rate | LP Comparators | TCPWM Blocks | SCB Blocks | Smart I/Os | GPIO | 35-ball WLCSP (0.35mm pitch) | 32-lead FN | 40L QFN | 48LD TQFP | 44LD TQFP | |
| | CY8C4146AZQ-S423 | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | -40°C to 105°C |
| | CY8C4146AXI-S423 | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 85°C |
| | CY8C4146AXQ-S423 | 48 | 64 | 8 | 2 | 0 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 105°C |
| | CY8C4146FNI-S433T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 31 | X | - | - | - | - | -40°C to 85°C |
| | CY8C4146FNQ-S433T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 31 | X | - | - | - | - | -40°C to 105°C |
| | CY8C4146LQI-S432T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 27 | - | X | - | - | - | -40°C to 85°C |
| | CY8C4146LQQ-S432T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 27 | - | X | - | - | - | -40°C to 105°C |
| | CY8C4146LQI-S433T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 34 | - | - | X | - | - | -40°C to 85°C |
| | CY8C4146AZI-S433T | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | -40°C to 85°C |
| | CY8C4146AZQ-S433 | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | X | - | -40°C to 105°C |
| | CY8C4146AXI-S433 | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 85°C |
| | CY8C4146AXQ-S433 | 48 | 64 | 8 | 2 | 1 | 1 | 1 | 1 Msps | 2 | 5 | 3 | 16 | 36 | - | - | - | - | X | -40°C to 105°C |

The nomenclature used in the preceding table is based on the following part numbering convention:

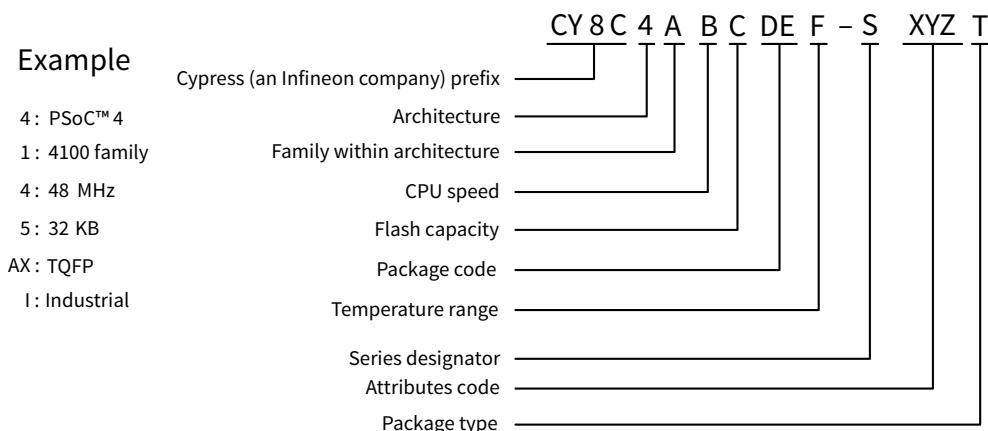
Table 40 Nomenclature

| Field | Description | Values | Meaning |
|-----------------------------|-------------|--------|---------|
| CY8C | Prefix | | |
| (table continues...) | | | |

Table 40 (continued) Nomenclature

| Field | Description | Values | Meaning |
|-------|-------------------|---------|--|
| 4 | Architecture | 4 | PSoC™ 4 |
| A | Family | 1 | 4100 Family |
| B | CPU speed | 2 | 24 MHz |
| | | 4 | 48 MHz |
| C | Flash capacity | 4 | 16 KB |
| | | 5 | 32 KB |
| | | 6 | 64 KB |
| | | 7 | 128 KB |
| DE | Package code | AX | TQFP (0.8 mm pitch) |
| | | AZ | TQFP (0.5 mm pitch) |
| | | LQ | QFN |
| | | PV | SSOP |
| | | FN | CSP |
| F | Temperature range | I | Industrial |
| | | Q | Extended Industrial |
| S | Series designator | S | S-Series |
| | | M | M-Series |
| | | L | L-Series |
| XYZ | Attributes code | 000-999 | Code of feature set in the specific family |
| T | Package type | | Tray |
| | | T | Tape and Reel |

The following is an example of a part number.



7 Packaging

7 Packaging

The PSoC™ 4100S is offered in 48LD TQFP, 44LD TQFP, 40L QFN, 32-lead QFN, and 35-ball WLCSP packages.

[Table 41](#) provides the package dimensions and Infineon drawing numbers.

Table 41 Package list

| Spec ID | Package | Description | Package drawing |
|---------|---------------|---|-----------------|
| BID20 | 48LD TQFP | 7 × 7 × 1.4-mm height with 0.5-mm pitch | 51-85135 |
| BID20A | 44LD TQFP | 10 × 10 × 1.6-mm height with 0.8-mm pitch | 51-85064 |
| BID27 | 40L QFN | 6 × 6 × 0.6-mm height with 0.5-mm pitch | 001-80659 |
| BID34A | 32-lead QFN | 5 × 5 × 0.6-mm height with 0.5-mm pitch | 001-42168 |
| BID34D | 35-ball WLCSP | 2.6 × 2.1 × 0.48-mm height with 0.35-mm pitch | 002-09958 |

Table 42 Package thermal characteristics

| Parameter | Description | Package | Min | Typ | Max | Unit | Details/ conditions |
|-----------------|--------------------------------|---------------|-----|------|-----|------|------------------------|
| T _A | Operating ambient temperature | - | -40 | 25 | 105 | °C | - |
| T _J | Operating junction temperature | - | -40 | - | 125 | | |
| T _{JA} | Package θ _{JA} | 48LD TQFP | - | 74.8 | - | °C/W | - |
| T _{JC} | Package θ _{JC} | 48LD TQFP | - | 35.7 | - | | - |
| T _{JA} | Package θ _{JA} | 44LD TQFP | - | 57.2 | - | | - |
| T _{JC} | Package θ _{JC} | 44LD TQFP | - | 17.5 | - | | - |
| T _{JA} | Package θ _{JA} | 40L QFN | - | 17.8 | - | | - |
| T _{JC} | Package θ _{JC} | 40L QFN | - | 2.8 | - | | - |
| T _{JA} | Package θ _{JA} | 32-lead QFN | - | 19.9 | - | | - |
| T _{JC} | Package θ _{JC} | 32-lead QFN | - | 4.3 | - | | - |
| T _{JA} | Package θ _{JA} | 35-ball WLCSP | - | 43 | - | | - |
| T _{JC} | Package θ _{JC} | 35-ball WLCSP | - | 0.3 | - | | - |

Table 43 Solder reflow peak temperature

| Package | Maximum peak temperature | Maximum time at peak temperature |
|---------|--------------------------|----------------------------------|
| All | 260°C | 30 seconds |

Table 44 Package moisture sensitivity level (MSL), IPC/JEDEC J-STD-020

| Package | MSL |
|------------------|-------|
| All except WLCSP | MSL 3 |
| 35-ball WLCSP | MSL 1 |

7.1 Package diagrams

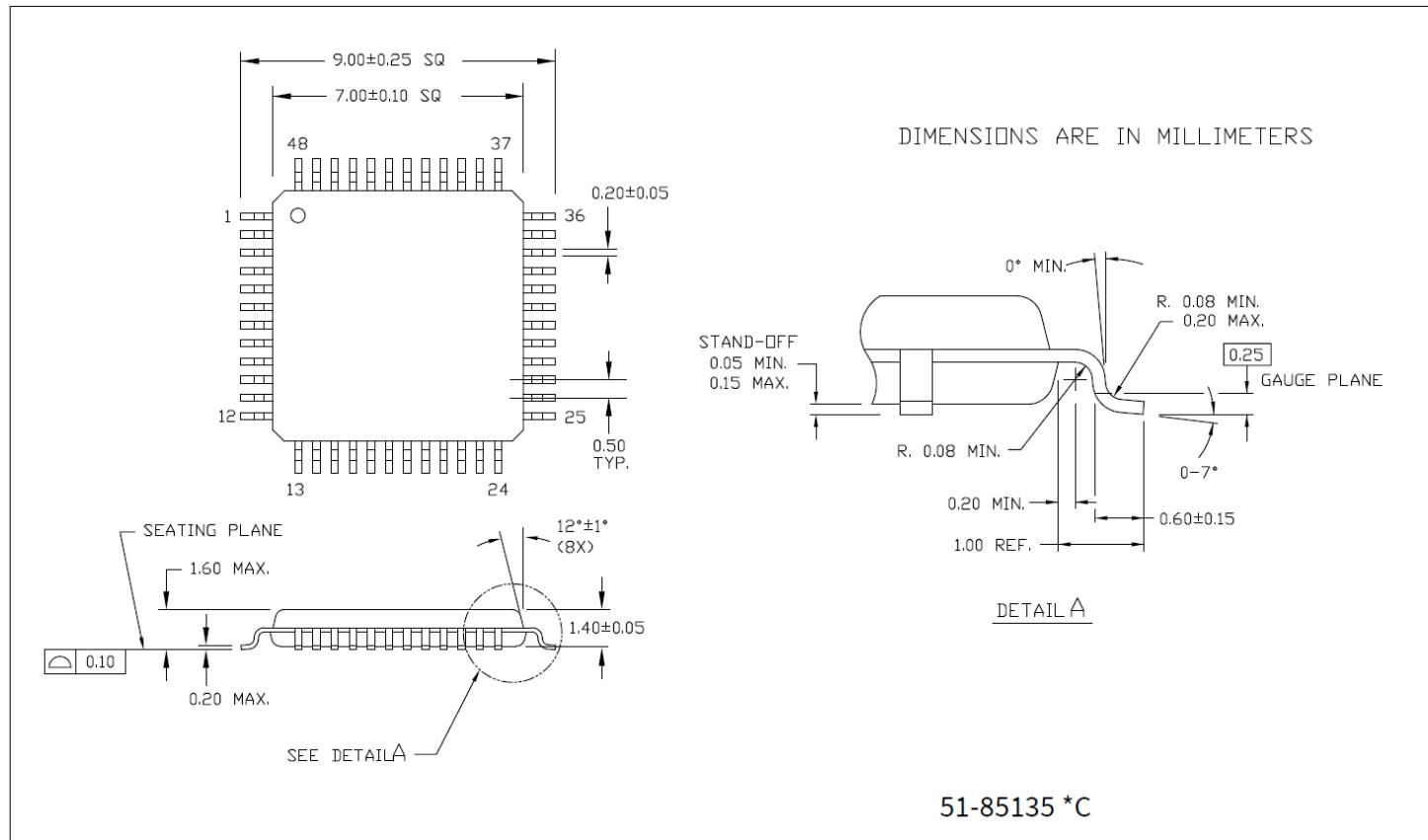


Figure 8 48LD TQFP 7x7x1.4 MM A48 package outline (PG-TQFP-48), 51-85135

7 Packaging

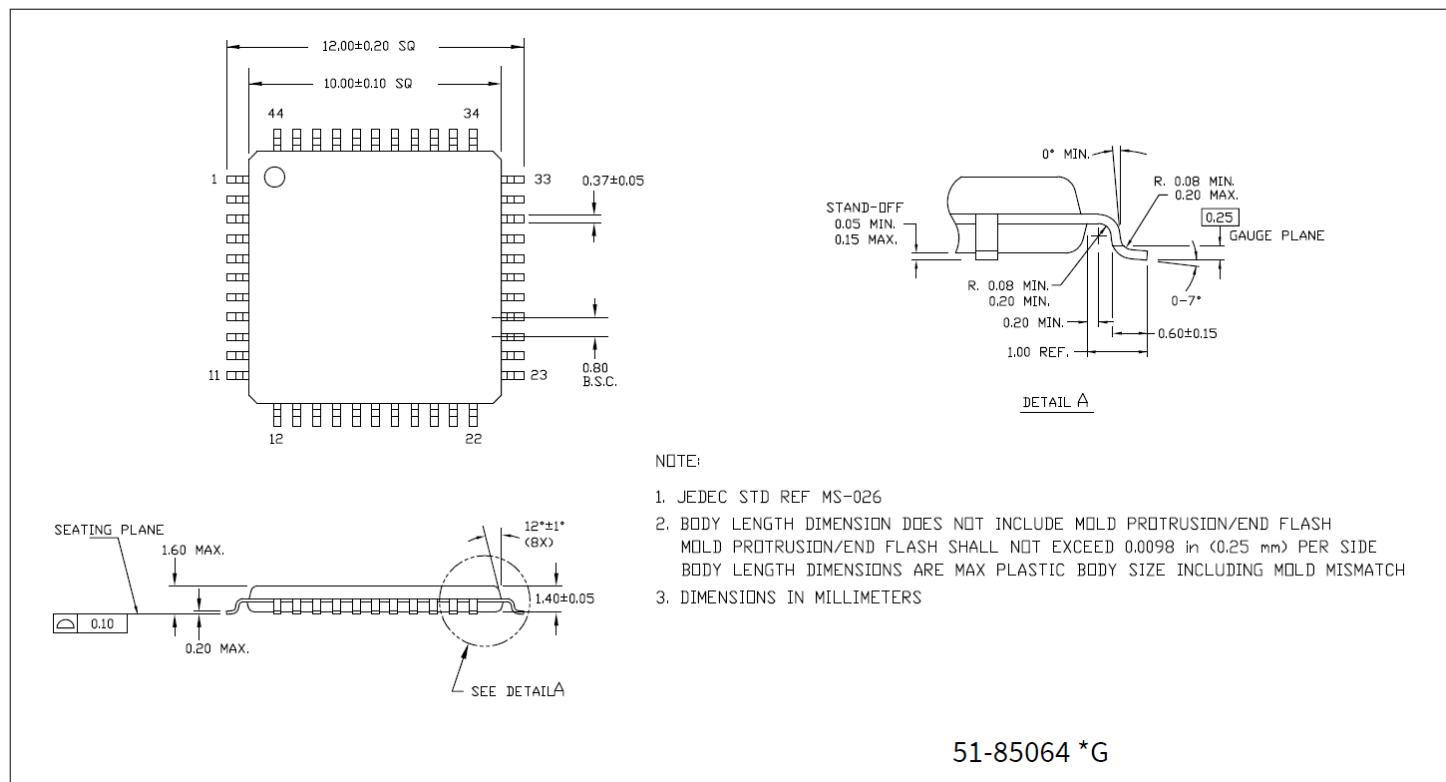
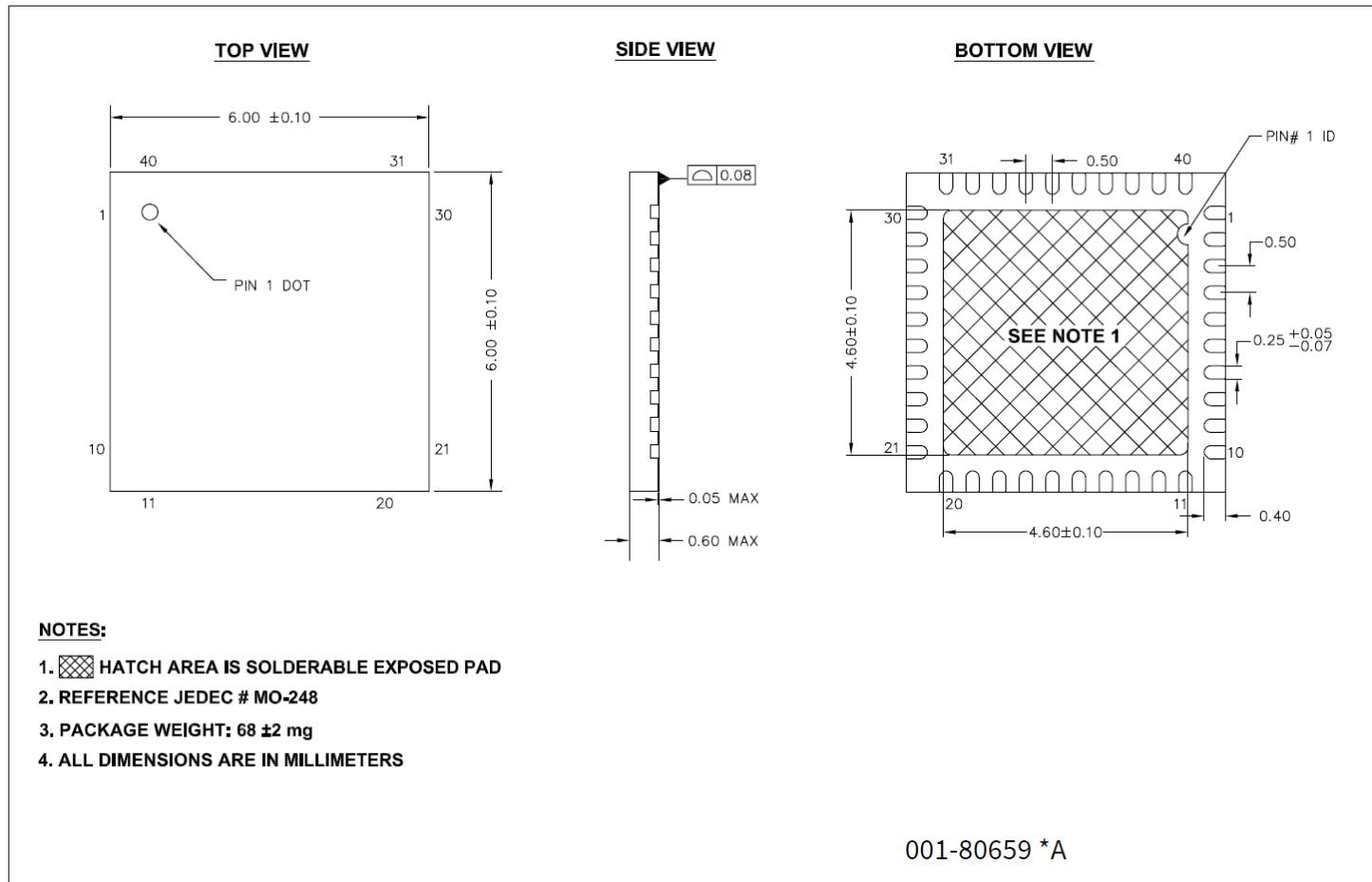


Figure 9 44LD TQFP 10×10×1.4 MM A44S package outline (PG-TQFP-44), 51-85064



**Figure 10 40L QFN 6x6x0.6 MM LR40A/LQ40A 4.6x4.6 E-PAD (SAWN) package outline (PG-VQFN-40),
 001-80659**

Note: The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

7 Packaging

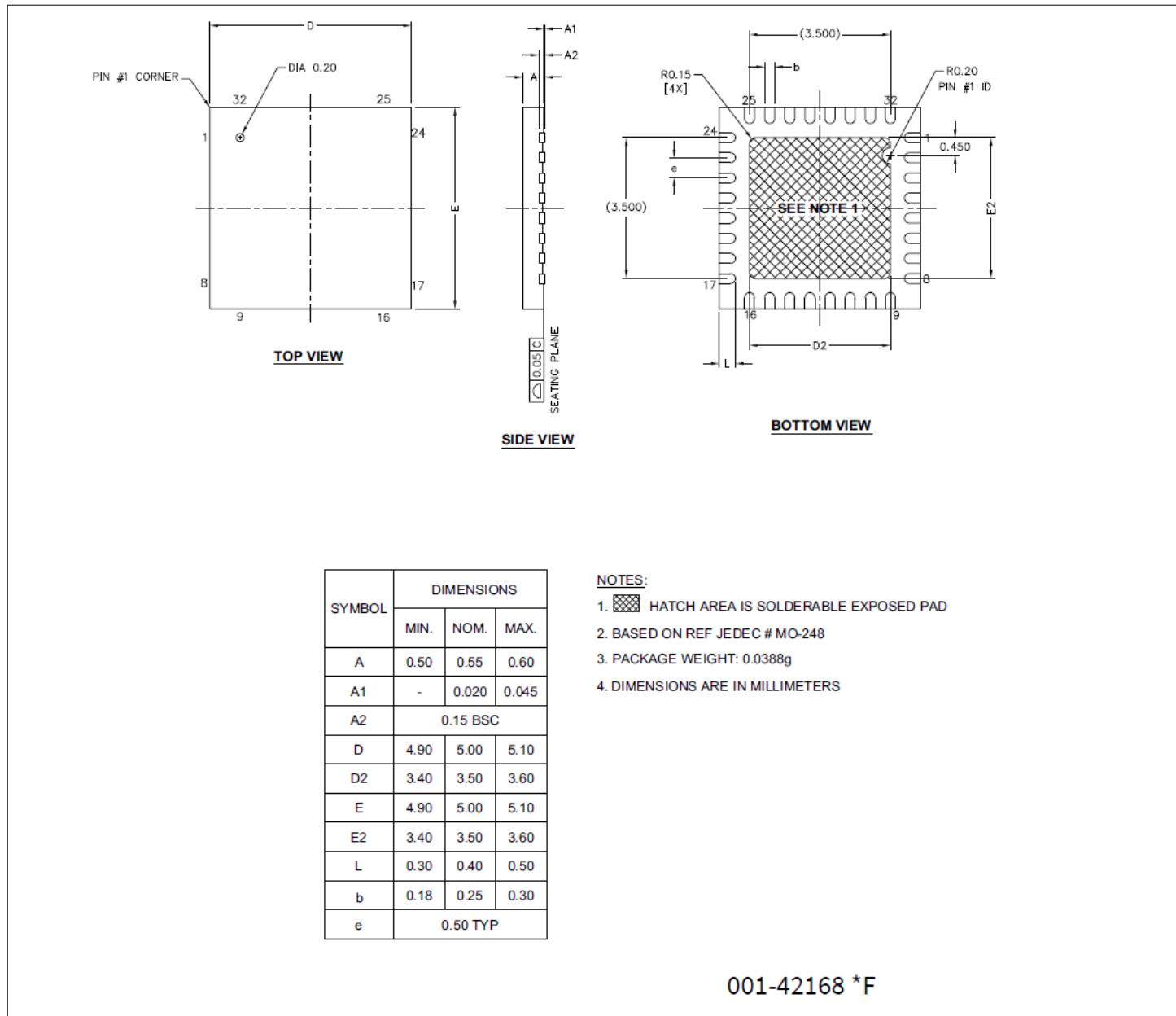


Figure 11 32 LEAD QFN 5.0×5.0×0.55 MM LQ32/LQ32B 3.5×3.5 MM EPAD (SAWN) package outline (PG-VQFN-32), 001-42168

Note: The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

7 Packaging

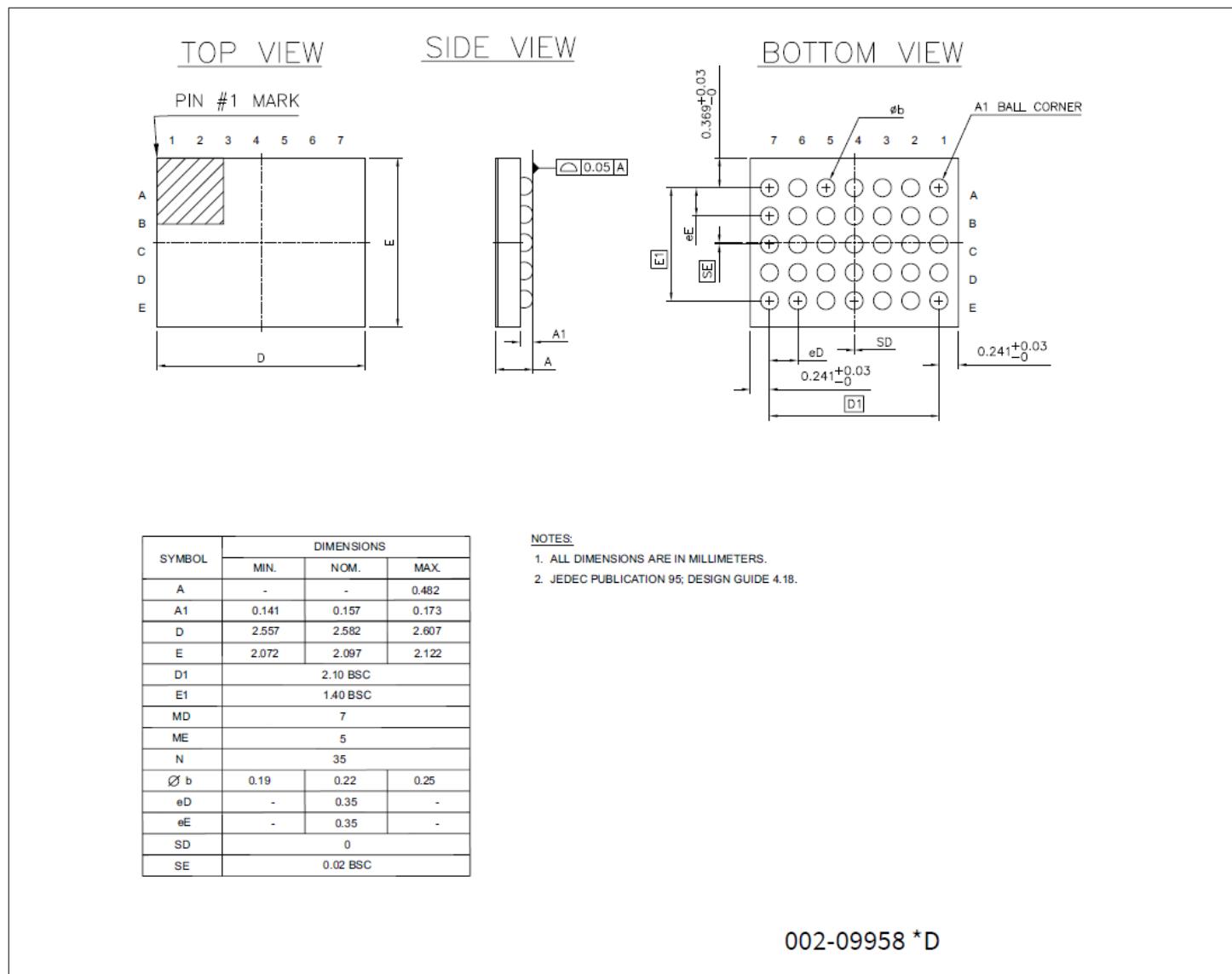


Figure 12

35 BALL WLCSP 2.582×2.097×0.482MM, FN35B package outline (SG-XFWLB-35), 002-09958

8 Acronyms

Table 45 Acronyms used in this document

| Acronym | Description |
|---------|--|
| abus | analog local bus |
| ADC | analog-to-digital converter |
| AG | analog global |
| AHB | AMBA (advanced microcontroller bus architecture) high-performance bus, an Arm® data transfer bus |
| ALU | arithmetic logic unit |
| AMUXBUS | analog multiplexer bus |
| API | application programming interface |
| APSR | application program status register |
| Arm® | advanced RISC machine, a CPU architecture |
| ATM | automatic thump mode |
| BW | bandwidth |
| CAN | Controller Area Network, a communications protocol |
| CMRR | common-mode rejection ratio |
| CPU | central processing unit |
| CRC | cyclic redundancy check, an error-checking protocol |
| DAC | digital-to-analog converter, see also IDAC, VDAC |
| DFB | digital filter block |
| DIO | digital input/output, GPIO with only digital capabilities, no analog. See GPIO. |
| DMIPS | Dhrystone million instructions per second |
| DMA | direct memory access, see also TD |
| DNL | differential nonlinearity, see also INL |
| DNU | do not use |
| DR | port write data registers |
| DSI | digital system interconnect |
| DWT | data watchpoint and trace |
| ECC | error correcting code |
| ECO | external crystal oscillator |
| EEPROM | electrically erasable programmable read-only memory |
| EMI | electromagnetic interference |
| EMIF | external memory interface |
| EOC | end of conversion |
| EOF | end of frame |

(table continues...)

Table 45 (continued) Acronyms used in this document

| Acronym | Description |
|--------------------------|--|
| EPSR | execution program status register |
| ESD | electrostatic discharge |
| ETM | embedded trace macrocell |
| FIR | finite impulse response, see also IIR |
| FPB | flash patch and breakpoint |
| FS | full-speed |
| GPIO | general-purpose input/output, applies to a PSoC™ pin |
| HVI | high-voltage interrupt, see also LVI, LVD |
| IC | integrated circuit |
| IDAC | current DAC, see also DAC, VDAC |
| IDE | integrated development environment |
| I ² C, or IIC | Inter-Integrated Circuit, a communications protocol |
| IIR | infinite impulse response, see also FIR |
| ILO | internal low-speed oscillator, see also IMO |
| IMO | internal main oscillator, see also ILO |
| INL | integral nonlinearity, see also DNL |
| I/O | input/output, see also GPIO, DIO, SIO, USBIO |
| IPOR | initial power-on reset |
| IPSR | interrupt program status register |
| IRQ | interrupt request |
| ITM | instrumentation trace macrocell |
| LCD | liquid crystal display |
| LIN | Local Interconnect Network, a communications protocol. |
| LR | link register |
| LUT | lookup table |
| LVD | low-voltage detect, see also LVI |
| LVI | low-voltage interrupt, see also HVI |
| LVTTL | low-voltage transistor-transistor logic |
| MAC | multiply-accumulate |
| MCU | microcontroller unit |
| MISO | master-in slave-out |
| NC | no connect |
| NMI | nonmaskable interrupt |

(table continues...)

Table 45 (continued) Acronyms used in this document

| Acronym | Description |
|----------------|---|
| NRZ | non-return-to-zero |
| NVIC | nested vectored interrupt controller |
| NVL | nonvolatile latch, see also WOL |
| opamp | operational amplifier |
| PAL | programmable array logic, see also PLD |
| PC | program counter |
| PCB | printed circuit board |
| PGA | programmable gain amplifier |
| PHUB | peripheral hub |
| PHY | physical layer |
| PICU | port interrupt control unit |
| PLA | programmable logic array |
| PLD | programmable logic device, see also PAL |
| PLL | phase-locked loop |
| PMDD | package material declaration data sheet |
| POR | power-on reset |
| PRES | precise power-on reset |
| PRS | pseudo random sequence |
| PS | port read data register |
| PSoC™ | Programmable System-on-Chip™ |
| PSRR | power supply rejection ratio |
| PWM | pulse-width modulator |
| RAM | random-access memory |
| RISC | reduced-instruction-set computing |
| RMS | root-mean-square |
| RTC | real-time clock |
| RTL | register transfer language |
| RTR | remote transmission request |
| RX | receive |
| SAR | successive approximation register |
| SC/CT | switched capacitor/continuous time |
| SCL | I2C serial clock |
| SDA | I2C serial data |

(table continues...)

Table 45 (continued) Acronyms used in this document

| Acronym | Description |
|----------------|--|
| S/H | sample and hold |
| SINAD | signal to noise and distortion ratio |
| SIO | special input/output, GPIO with advanced features. See GPIO. |
| SOC | start of conversion |
| SOF | start of frame |
| SPI | Serial Peripheral Interface, a communications protocol |
| SR | slew rate |
| SRAM | static random access memory |
| SRES | software reset |
| SWD | serial wire debug, a test protocol |
| SWV | single-wire viewer |
| TD | transaction descriptor, see also DMA |
| THD | total harmonic distortion |
| TIA | transimpedance amplifier |
| TTL | transistor-transistor logic |
| TX | transmit |
| UART | Universal Asynchronous Transmitter Receiver, a communications protocol |
| UDB | universal digital block |
| USB | universal serial bus |
| USBIO | USB input/output, PSoC™ pins used to connect to a USB port |
| VDAC | voltage DAC, see also DAC, IDAC |
| WDT | watchdog timer |
| WOL | write once latch, see also NVL |
| WRES | watchdog timer reset |
| XRES | external reset I/O pin |
| XTAL | crystal |

9 Document conventions

9.1 Units of measure

Table 46 Units of measure

| Symbol | Unit of measure |
|---------------|------------------------|
| °C | degrees celsius |
| dB | decibel |
| fF | femto farad |
| Hz | hertz |
| KB | 1024 bytes |
| kbps | kilobits per second |
| Khr | kilohour |
| kHz | kilohertz |
| kΩ | kilo ohm |
| ksps | kilosamples per second |
| LSB | least significant bit |
| Mbps | megabits per second |
| MHz | megahertz |
| MΩ | mega-ohm |
| Msps | megasamples per second |
| µA | microampere |
| µF | microfarad |
| µH | microhenry |
| µs | microsecond |
| µV | microvolt |
| µW | microwatt |
| mA | milliampere |
| ms | millisecond |
| mV | millivolt |
| nA | nanoampere |
| ns | nanosecond |
| nV | nanovolt |
| Ω | ohm |
| pF | picofarad |
| ppm | parts per million |
| ps | picosecond |

(table continues...)

Table 46 (continued) Units of measure

| Symbol | Unit of measure |
|---------------|------------------------|
| s | second |
| sps | samples per second |
| sqrtHz | square root of hertz |
| V | volt |

Revision history

Revision history

| Document revision | Date | Description of changes |
|-------------------|------------|---|
| ** | 2015-08-28 | New datasheet. |
| *A | 2015-10-30 | <p>Updated Pinouts: Updated Table 1.</p> <p>Updated Electrical specifications: Updated Analog peripherals: Updated Comparator: Updated Table 11. Updated Table 12.</p> <p>Updated 10-bit CAPSENSE™ ADC: Updated Table 16.</p> <p>Updated Ordering information: Updated part numbers. Completing Sunset Review</p> |
| *B | 2015-12-08 | Changed status from Advance to Preliminary. |
| *C | 2015-12-22 | <p>Updated Features: Updated description under “32-bit MCU Subsystem” and “Serial Communication”.</p> <p>Updated Pinouts: Updated Table 1. Updated Table 2.</p> <p>Updated Ordering information: No change in part numbers. Replaced “36 WLCSP (0.35 mm pitch)” with “35-WLCSP”.</p> <p>Updated Packaging: Replaced “36-ball WLCSP package” with “35-ball WLCSP package” in all instances. Completing Sunset Review.</p> |
| *D | 2016-02-16 | <p>Updated Packaging: Updated Table 42.</p> <p>Replaced TBD with 002-09958 *A. Added Errata. Updated to new template. Completing Sunset Review.</p> |

Revision history

| Document revision | Date | Description of changes |
|--------------------------|-------------|--|
| *E | 2016-03-15 | <p>Updated Electrical specifications: Updated Device level specifications: Updated XRES: Updated Table 8. Updated Table 9. Updated Analog peripherals: Updated CSD and IDAC: Updated Table 15. Updated 10-bit CAPSENSE™ ADC: Updated Table 16. Updated Memory: Updated Flash: Updated Table 27. Completing Sunset Review.</p> |
| *F | 2016-07-27 | <p>Updated Electrical specifications: Updated Analog peripherals: Updated CSD and IDAC: Updated Table 15. Updated 10-bit CAPSENSE™ ADC: Updated Table 16. Removed Errata. Completing Sunset Review. Release to web.</p> |
| *G | 2016-10-13 | <p>Added 44LD TQFP package related information related information in all instances across the document. Updated Packaging: Added 51-85064 *G.</p> |
| *H | 2017-01-09 | <p>Updated Functional definition: Updated Analog blocks: Updated 12-bit SAR ADC: Updated Figure 5. Updated Programmable digital blocks: Updated description. Updated Pinouts: Updated description. Updated Electrical specifications: Updated Device level specifications: Updated Table 4. Updated Ordering information: Updated part numbers. Completing Sunset Review.</p> |

Revision history

| Document revision | Date | Description of changes |
|--------------------------|-------------|---|
| *I | 2017-04-26 | <p>Updated Packaging: spec 002-09958 – Changed revision from *C to *D. Updated to new template.</p> |
| *J | 2018-02-14 | <p>Updated Features: Updated description under “Timing and Pulse-Width Modulation”. Added “Clock Sources”.</p> <p>Updated Development ecosystem: Updated description.</p> <p>Updated Block diagram.</p> <p>Updated Functional definition:</p> <p>Updated System resources:</p> <p>Updated Clock system:</p> <p>Updated Figure 4.</p> <p>Updated Pinouts:</p> <p>Updated Table 2.</p> <p>Updated Ordering information:</p> <p>Updated part numbers.</p> <p>Updated Packaging: spec 001-42168 – Changed revision from *E to *F. Updated to new template.</p> |
| *K | 2018-04-03 | <p>Updated Functional definition:</p> <p>Updated System resources:</p> <p>Updated Clock system:</p> <p>Updated Figure 4.</p> <p>Updated Watchdog timer and counters:</p> <p>Replaced “Watchdog Timer” with “Watchdog timer and counters” in heading.</p> <p>Updated description.</p> |

Revision history

| Document revision | Date | Description of changes |
|-------------------|------------|--|
| *L | 2018-10-30 | <p>Updated Features:</p> <p>Updated description under “32-bit MCU Subsystem”.</p> <p>Updated Block diagram (Corrected typo).</p> <p>Updated Functional definition:</p> <p>Updated System resources:</p> <p>Updated Watch Crystal Oscillator (WCO):</p> <p>Updated description.</p> <p>Updated Electrical specifications:</p> <p>Updated Analog peripherals:</p> <p>Updated CTBm Opamp:</p> <p>Updated Table 10.</p> <p>Updated SAR:</p> <p>Updated Table 14.</p> <p>Updated CSD and IDAC:</p> <p>Updated Table 15.</p> <p>Updated Digital peripherals:</p> <p>Updated SPI:</p> <p>Updated Table 21.</p> <p>Completing Sunset Review.</p> |
| *M | 2019-07-05 | <p>Added extended industrial temperature range related information in all instances across the document.</p> <p>Updated Electrical specifications:</p> <p>Updated Memory:</p> <p>Updated Flash:</p> <p>Updated Table 27.</p> <p>Updated Ordering information:</p> <p>Updated part numbers.</p> |
| *N | 2020-11-10 | <p>Updated Features:</p> <p>Added “ModusToolbox™ software”.</p> <p>Updated Development ecosystem:</p> <p>Added ModusToolbox™ software.</p> <p>Updated PSoC™ Creator:</p> <p>Updated description.</p> <p>Updated Table 27: Updated SID182B.</p> <p>Updated Table 32: Added SID223A.</p> <p>Updated Ordering information:</p> <p>Updated part numbers.</p> <p>Completing Sunset Review.</p> |
| *O | 2022-07-28 | <p>Updated Table 32: Updated spec SID223 and SID223A. Added specs SID223B through SID223D.</p> <p>Updated Ordering information:</p> <p>Updated part numbers.</p> <p>Migrated to Infineon template.</p> |
| *P | 2023-01-23 | Updated the footnotes in IMO AC specifications . |

Revision history

| Document revision | Date | Description of changes |
|-------------------|------------|--|
| *Q | 2024-02-27 | <p>Added note under 40L and 32-lead QFN package diagrams.</p> <p>Removed extra pin "DN" and pin name "VSSD" from 40L QFN column in Table 1.</p> <p>Content migrated to PRISMA.</p> <p>Fixed broken links.</p> <p>Updated the title to "PSoC™ 4100S based on Arm® Cortex®-M0+ CPU".</p> <p>Updated packaging diagram titles with IFX package code for Figure 8, Figure 9, Figure 10, Figure 11, and Figure 12.</p> <p>Updated package information in Table 39, Table 41, and Table 42.</p> <p>Updated package information across the datasheet.</p> <p>Updated CY8C4146LQQ-S422T to CY8C4146LQQ-S422 in Ordering information.</p> |

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Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.